
Intelligent Control Systems

Cameras and Image Sensors

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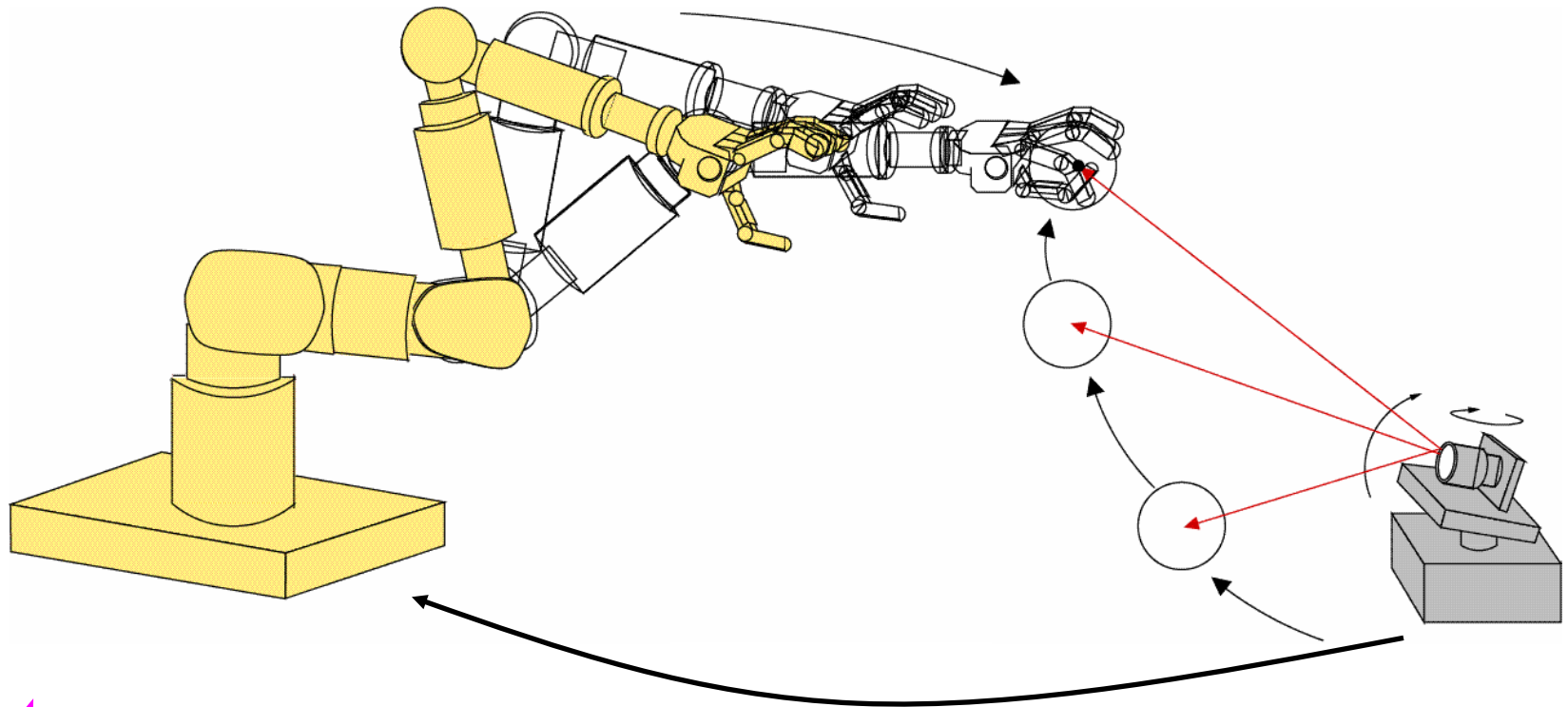
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<http://www.ic.is.tohoku.ac.jp/ja/swk/>

Basic Motivation

e.g. Vision-based Control of Robots



- image acquisition (today)
- image processing (from next week and on)
- robot control

Schedule (tentative)

June 7: Cameras and Image Sensors

June 14: Image Processing Fundamentals

* June 21 and 25 (Sat.): canceled

June 28: Basic Image Processing (1)

July 5: Basic Image Processing (2)

July 12: Object Tracking (1)

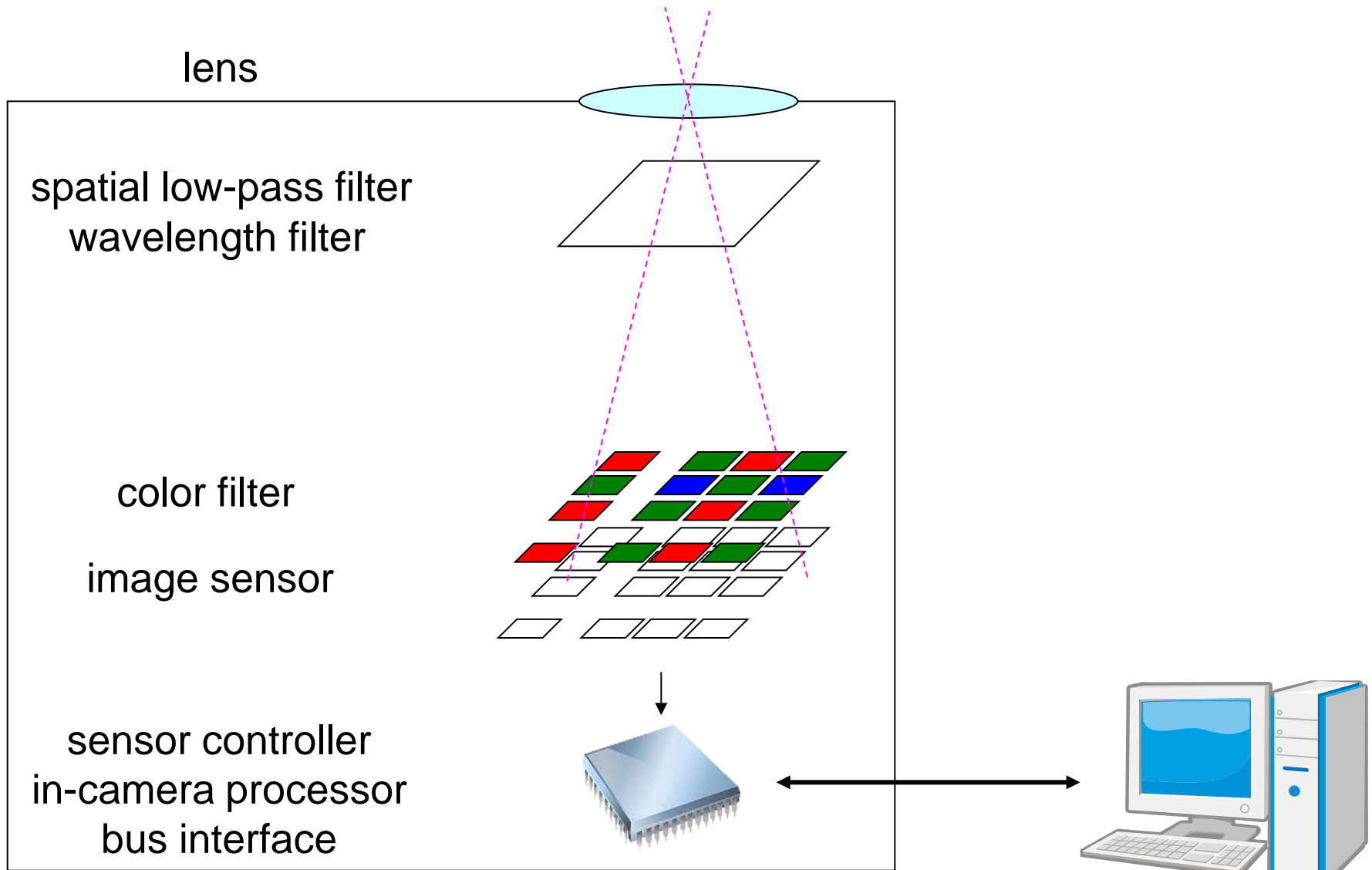
July 19: Object Tracking (2)

July 26: Speeding-Up Image Processing

Outline

- Lens and Optical Parts
- Image Sensors
 - CCD / CMOS sensors
 - Integration / Shutter Modes
- In-Camera Image Processing
- Image Data Transfer
- Dynamic Range Enhancement

Cameras and Image Sensors



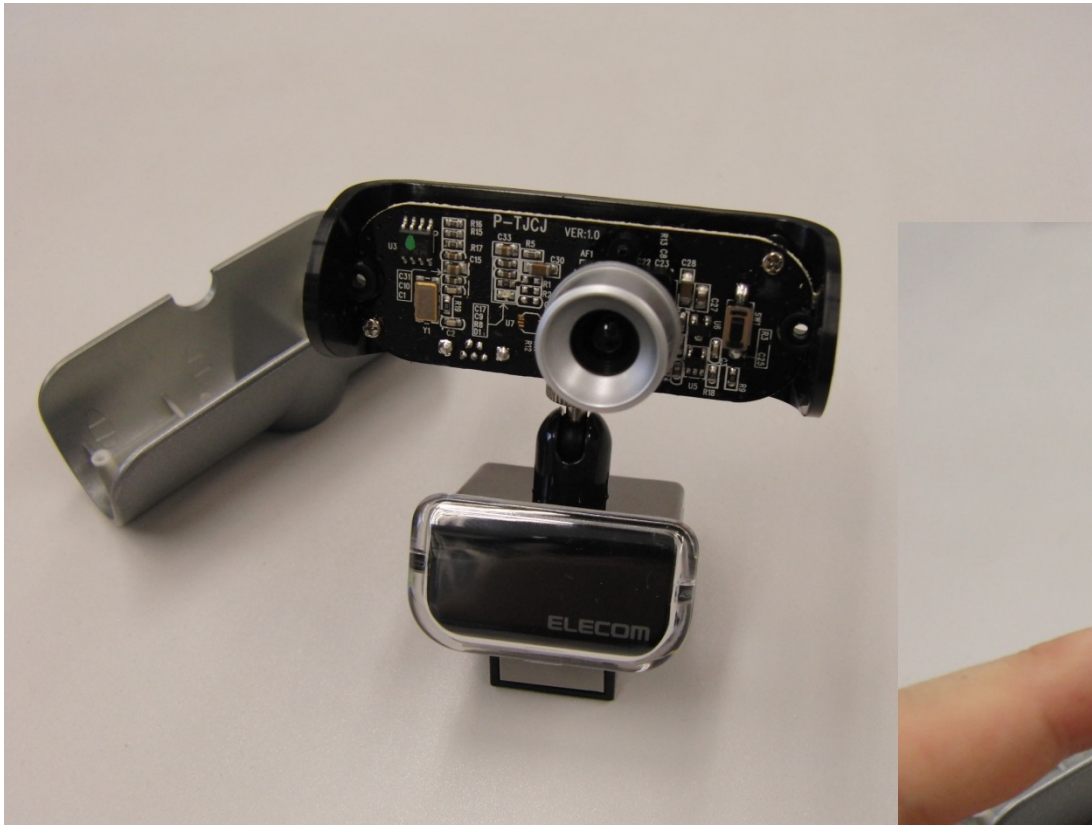
camera

Examples

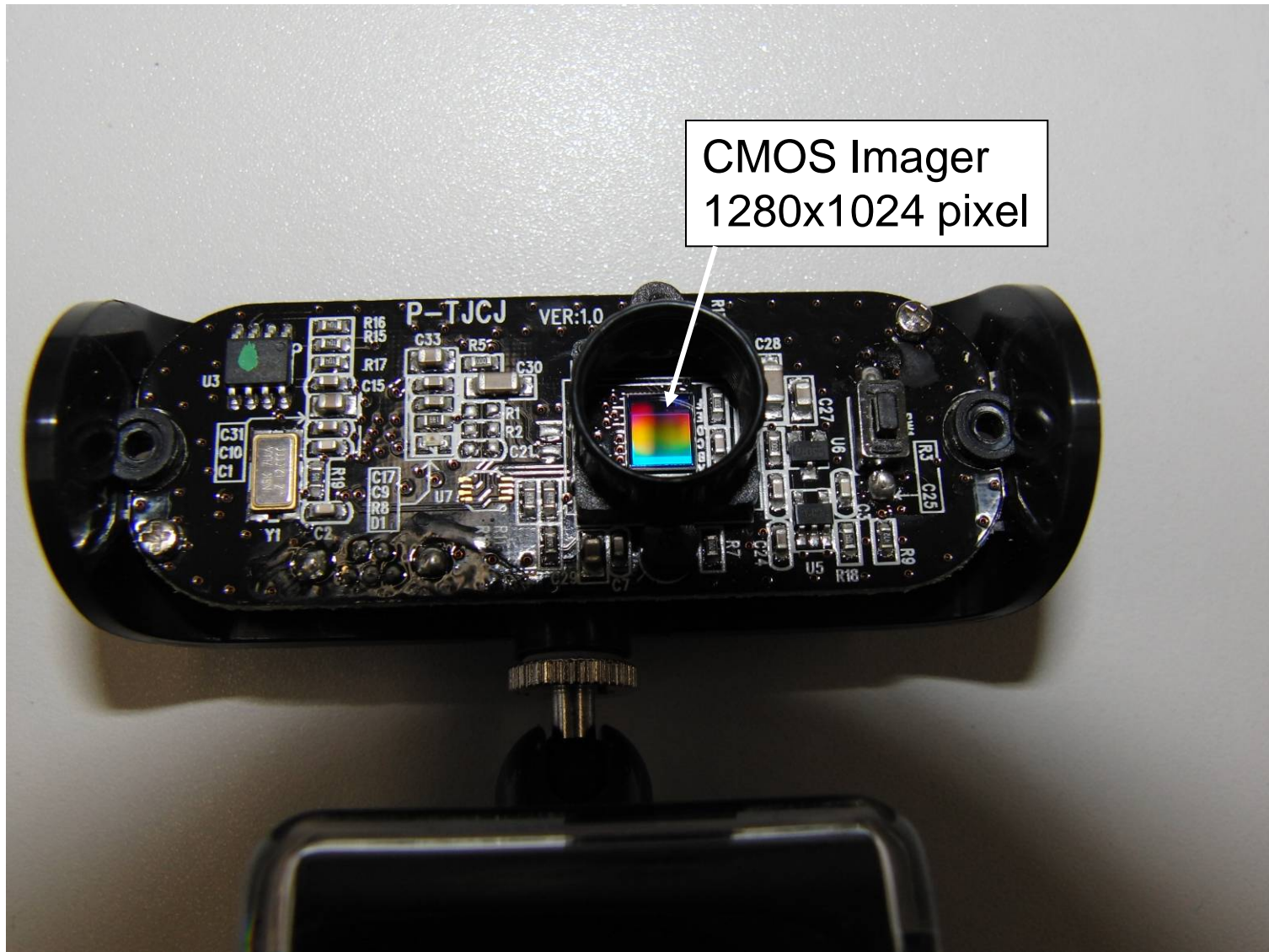


USB camera
with unremovable lens

Example



Example



Camera and Lens

Cameras with unremovable lens

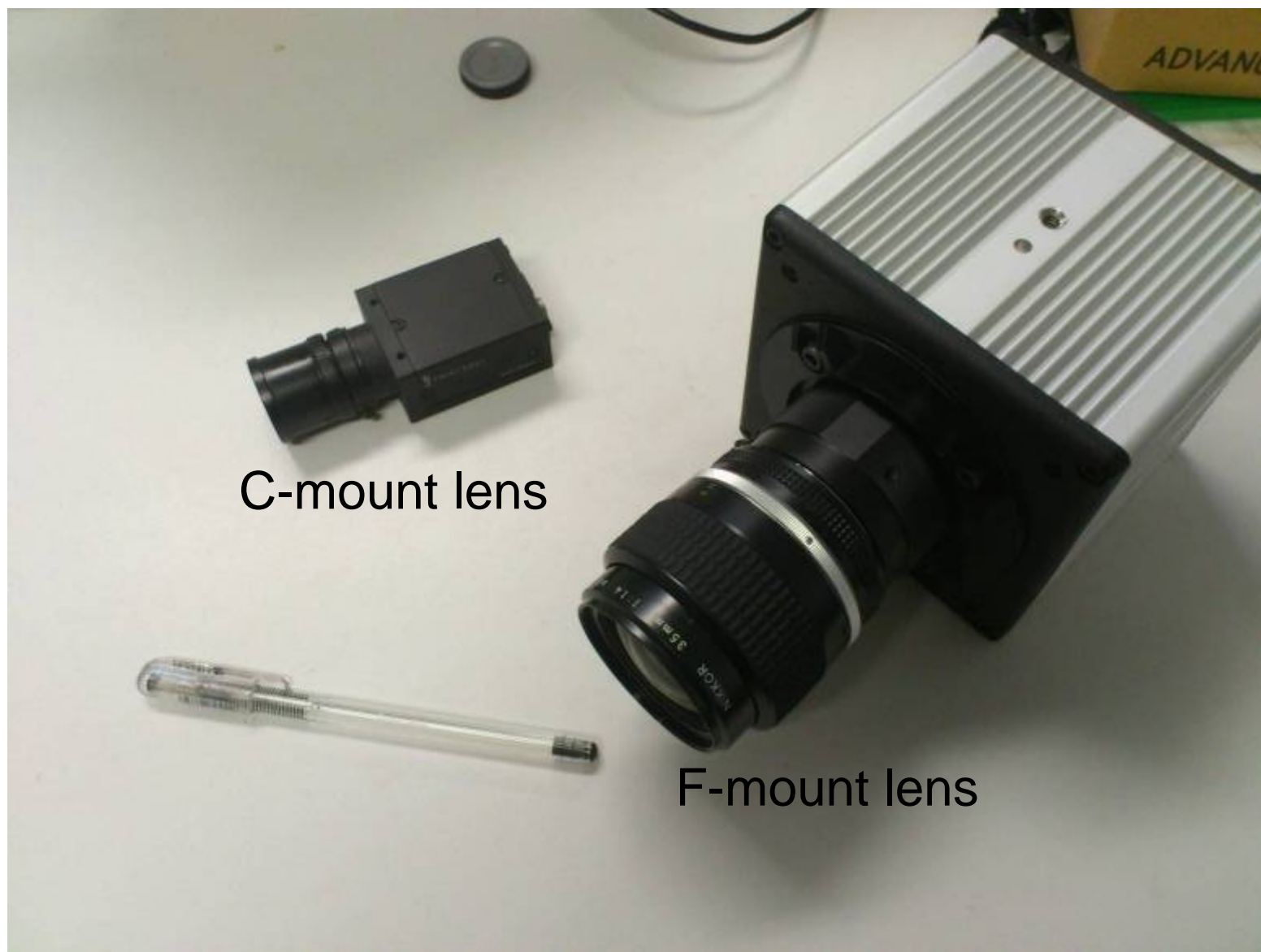
- most of inexpensive web cameras

Cameras with removable lens

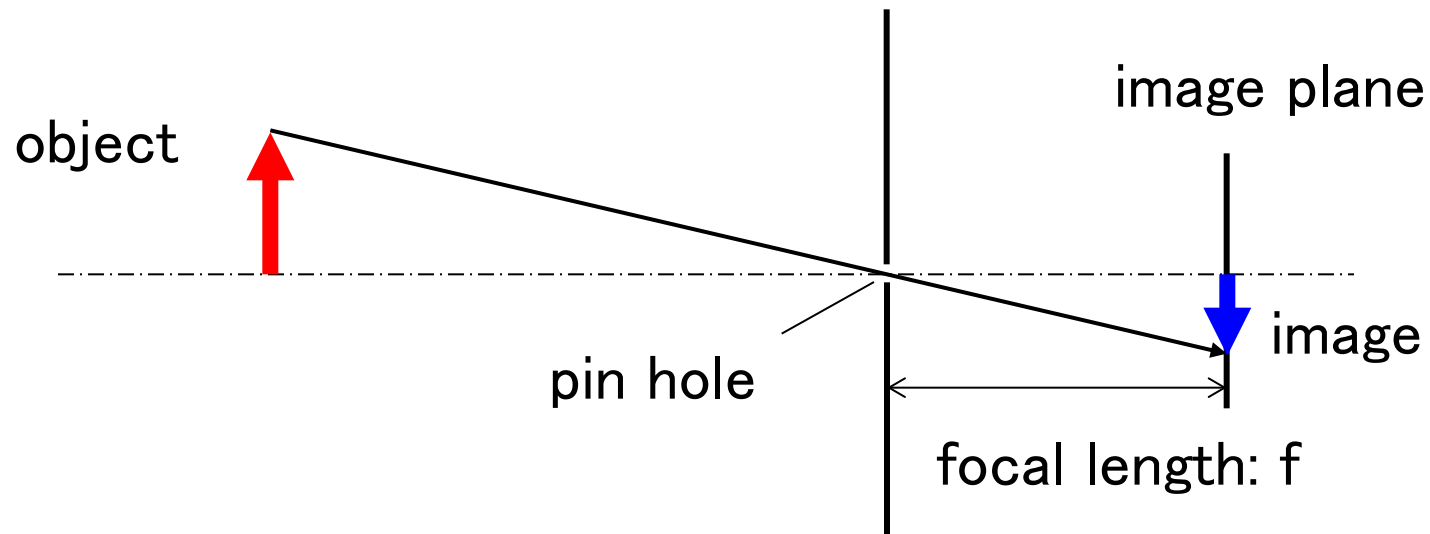
- Nikon F-mount (large aperture size)
- C-mount (small aperture, long flange back)
- CS-mount (same aperture with C-mount, short flange back)

- The lens must be selected considering the imager size
 - 1", 2/3", 1/2", 1/3", 1/4"
 - 1" corresponds approx. to diagonal length $D = 16$ mm
- View angle θ determined by D and focal length f
 - $\tan(\theta/2) = D/2f$
- F-number: f / A (A : aperture size)
 - The smaller, the brighter but narrower depth of field

C-mount / F-mount Lenses

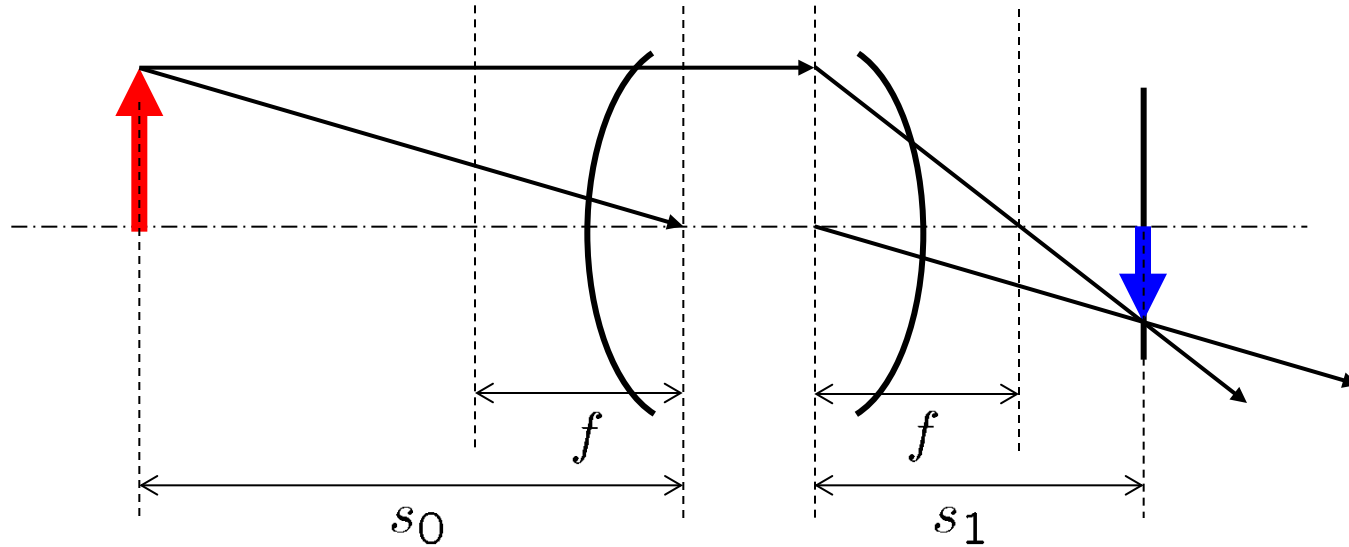


Pin-Hole Camera Model



- No restriction on the distance from camera to object
- Limited light amount available (dark image)

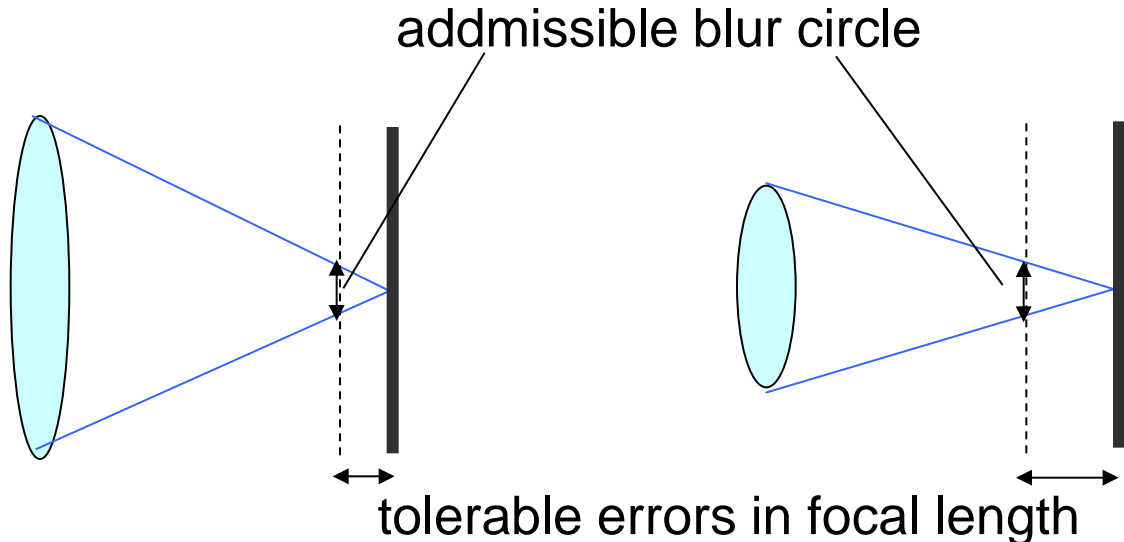
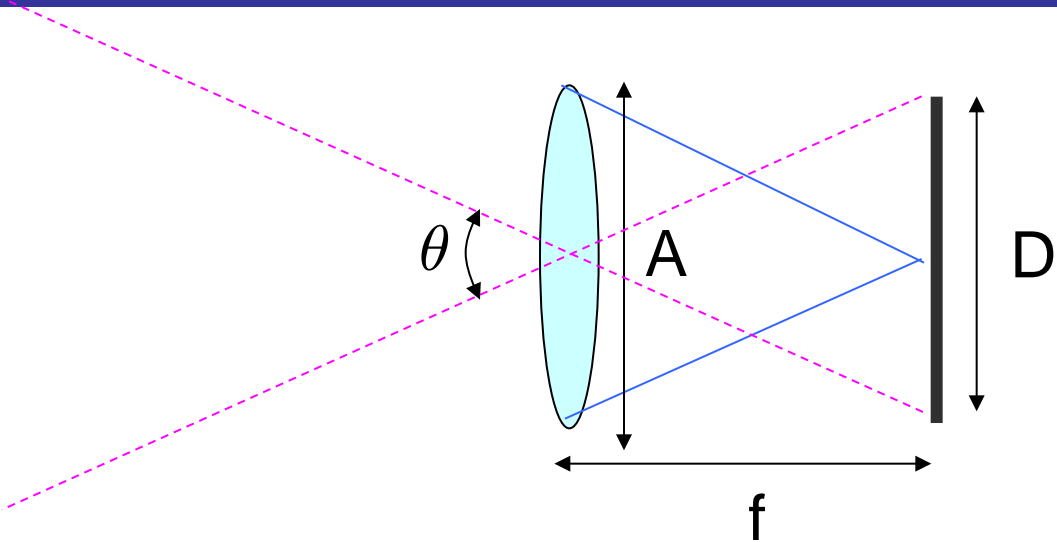
Lens formula



$$\frac{1}{f} = \frac{1}{s_0} + \frac{1}{s_1}$$

- More light is available than with pin hole
- Restricted distance from camera to object (Once f and s_1 are given, s_0 is uniquely determined)

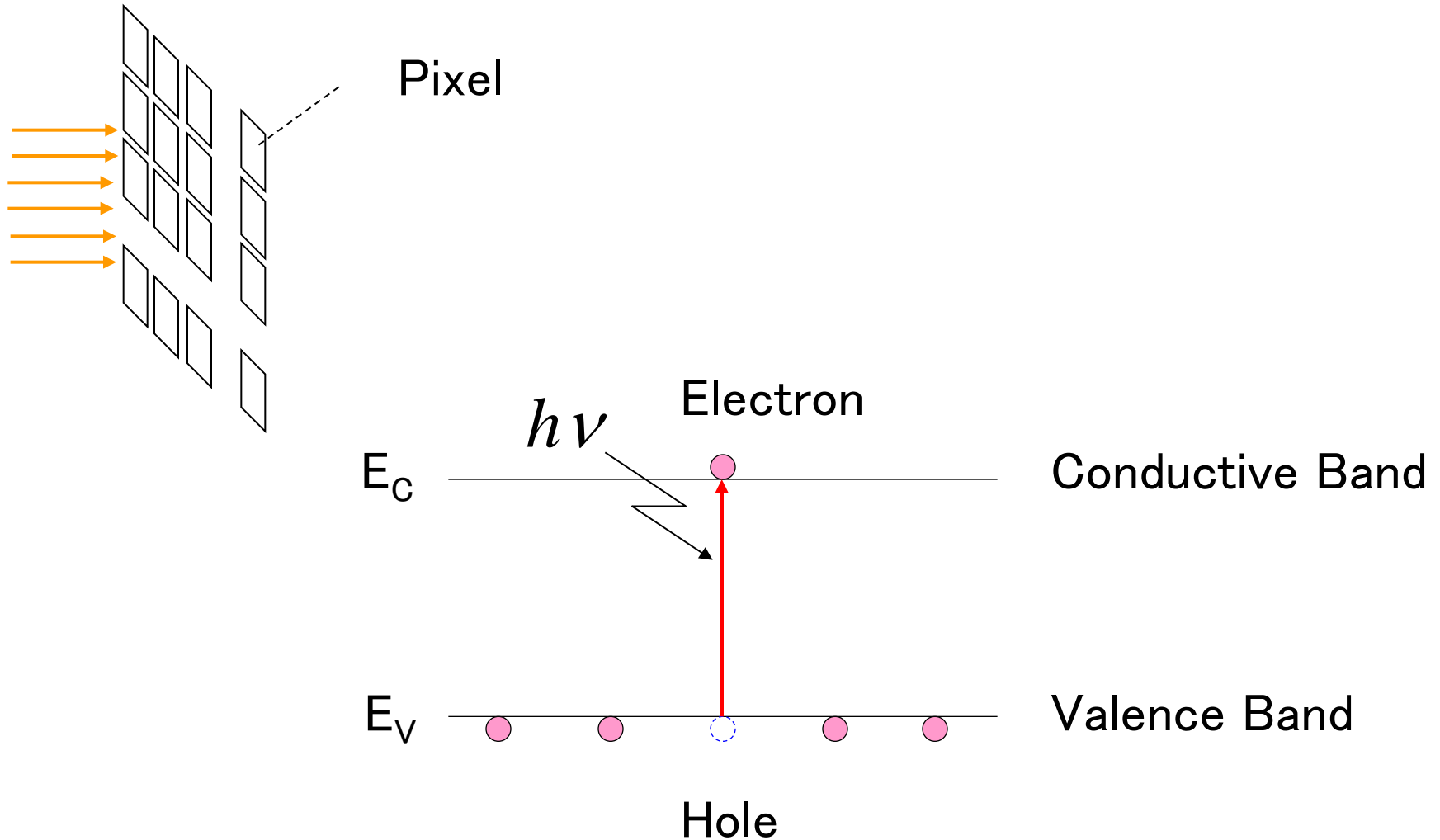
Imager size, Aperture size and Focal length



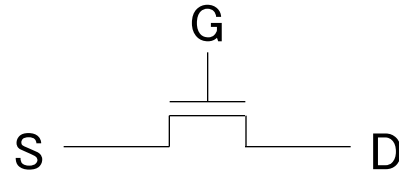
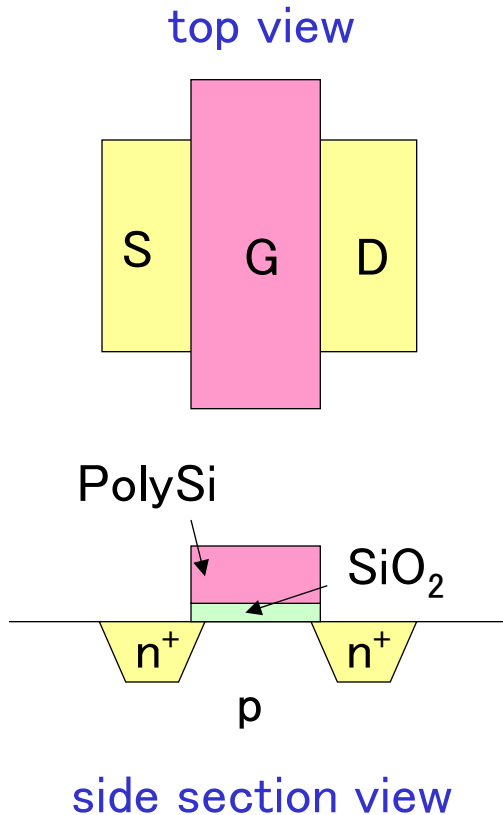
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Solid-State Image Sensor

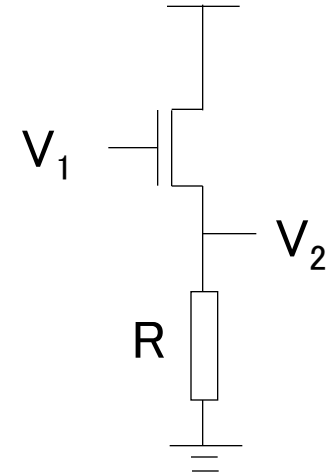


Minimal Knowledge of Semiconductor Devices



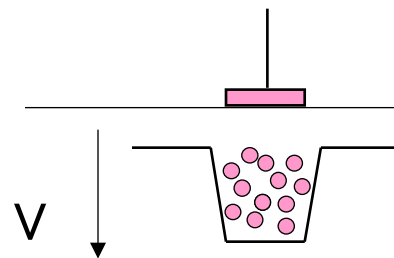
MOS switch

When V_G is high, S and G are connected (switch on)



Source Follower Amp.

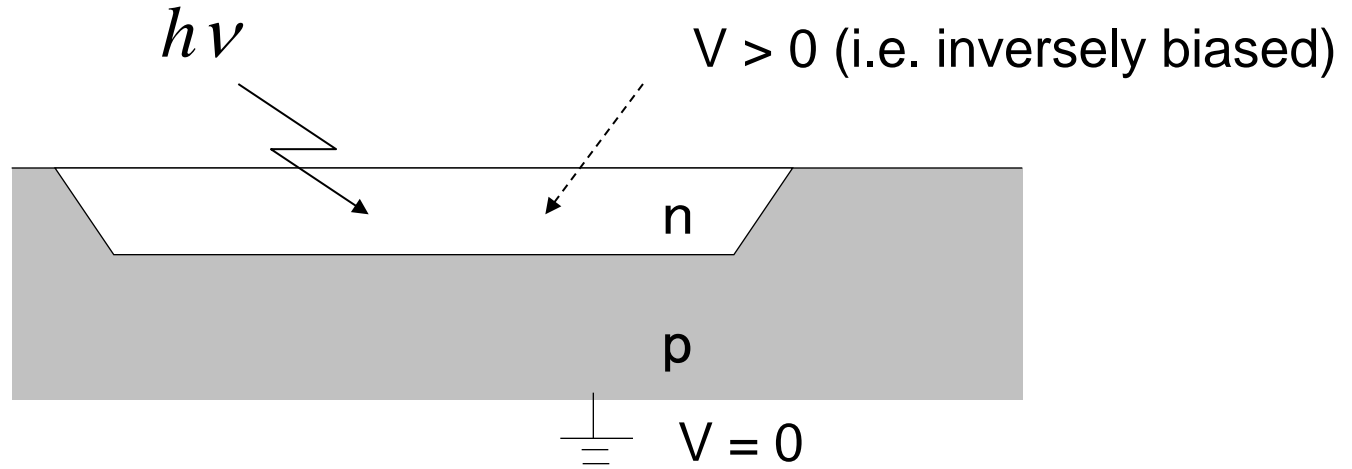
$$V_2 = V_1 + \alpha$$



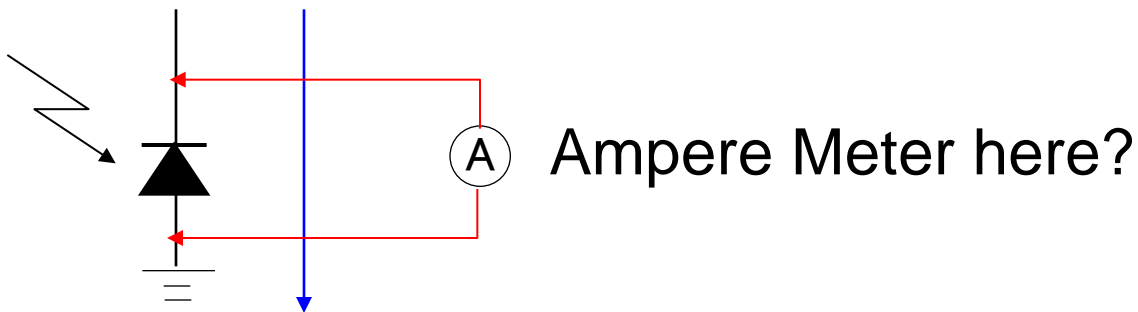
Potential Well

By applying locally high voltage, electronic charges can be collected

Photodiode

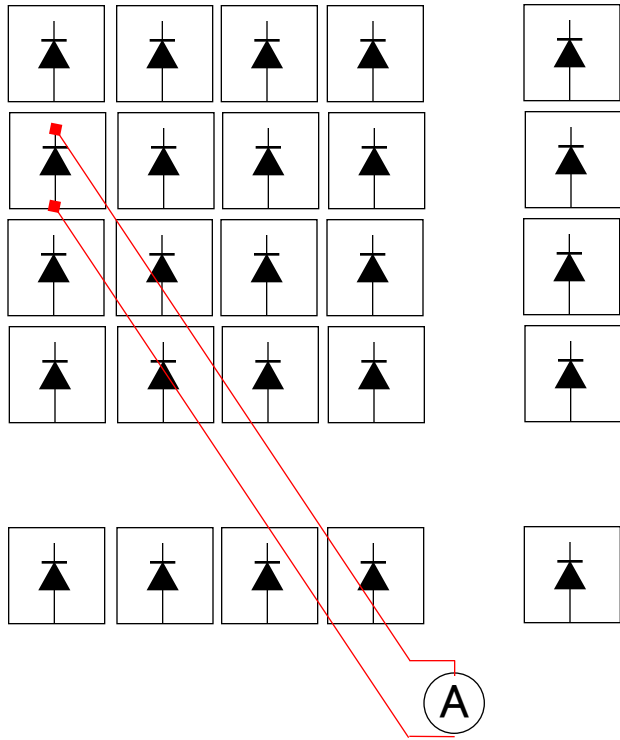


An intuitive interpretation:



photocurrent i : proportional to brightness

What if ampere meter is used



- Photocurrent is very weak
 - order of pA ~ fA
 - too susceptible to noise
- Difficult to measure millions of pixels at the same time, so time division is mandatory
 - for most of the time, photocurrent is just disposed

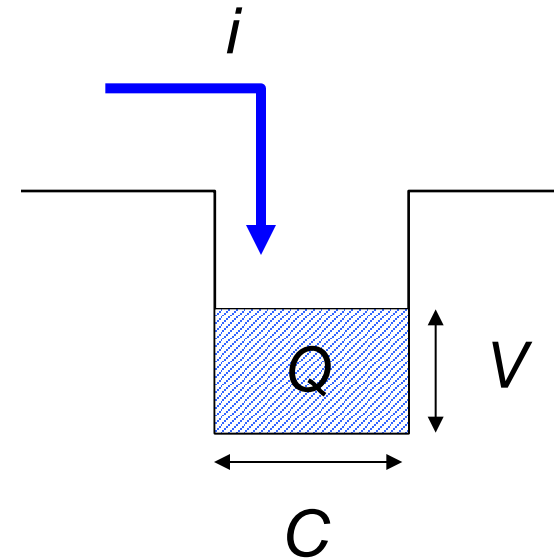
Photo Integration

That is why we need integration:

$$Q = \int_0^{t_{\text{int}}} i dt \quad : \text{charge}$$

$$V = \frac{Q}{C} \quad : \text{voltage}$$

C: capacitance of the node where the charges are integrated



Photocurrent is *integrated* over a certain integration time in a pixel *while the other pixels are read out*

Shot Noise

Fundamental noise in optical measurement: fluctuation in the number of the particles such as electrons and photons

$$N_{\text{shot,rms}} = \sqrt{\bar{N}}$$

$N_{\text{shot,rms}}$: root mean square # of shot noise charges

\bar{N} : # of signal charges

Equivalently,

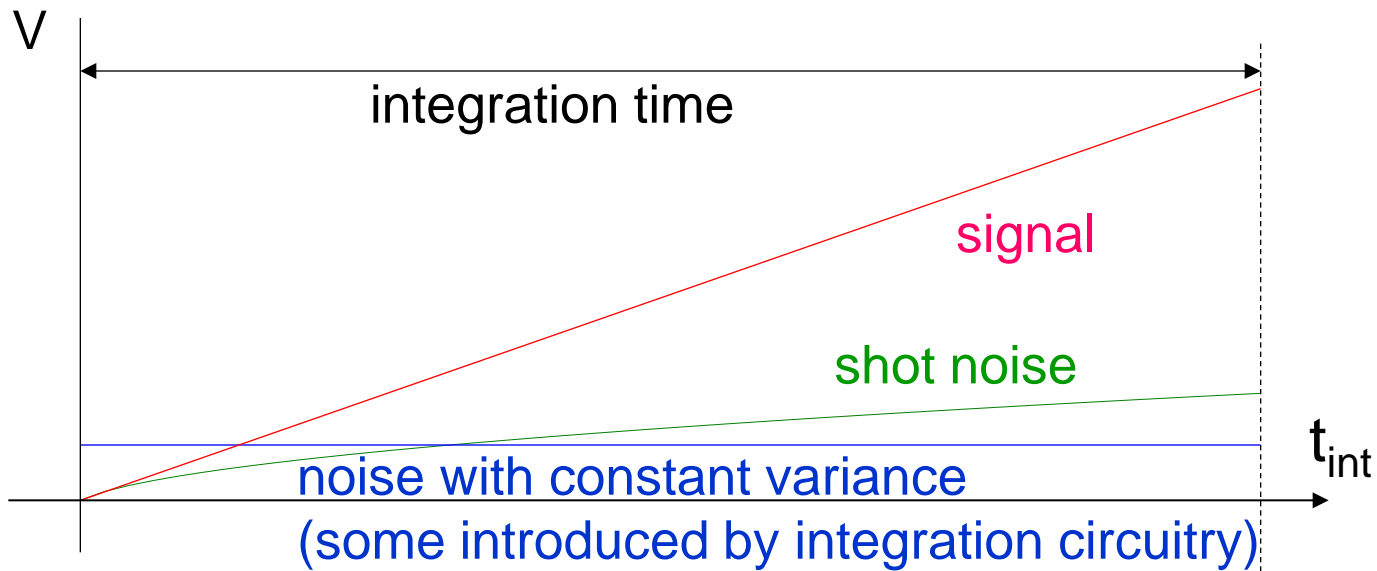
$$Q_{\text{shot,rms}} = e\sqrt{\bar{N}} = e\sqrt{\bar{i}t_{\text{int}}/e} = \sqrt{e\bar{i}t_{\text{int}}}$$

e : electron charge

\bar{i} : average photocurrent plus dark current

t_{int} : integration time

Noise and Integration time



$$V_{\text{signal}} = \frac{i_{\text{signal}} t_{\text{int}}}{C} \quad V_{\text{shot,rms}} = \frac{Q_{\text{shot,rms}}}{C} = \frac{\sqrt{e \bar{i} t_{\text{int}}}}{C}$$

With N times longer t_{int} , signal-to-noise ratio (SNR) is multiplied by:

- \sqrt{N} with respect to shot noise
- N with respect to other noise

Effects of Integration

- The longer the integration time is, the brighter the image becomes (because more photo signal is collected)
 - This is intuitive way of understanding; but it should be understood in terms of SNR
- Integration time \leq Frame time: Thus high frame rate imaging makes images darker (or more correctly, noisier)
 - Strong illumination may be needed
- Motion blur is caused when the scene moves fast

Integration-mode photodiode

positively biased and electrically floating

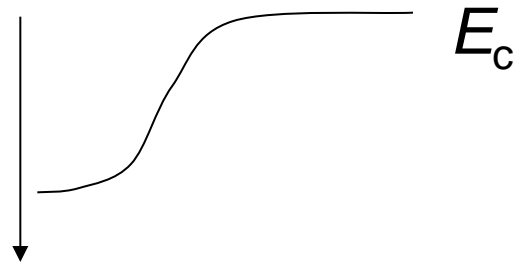
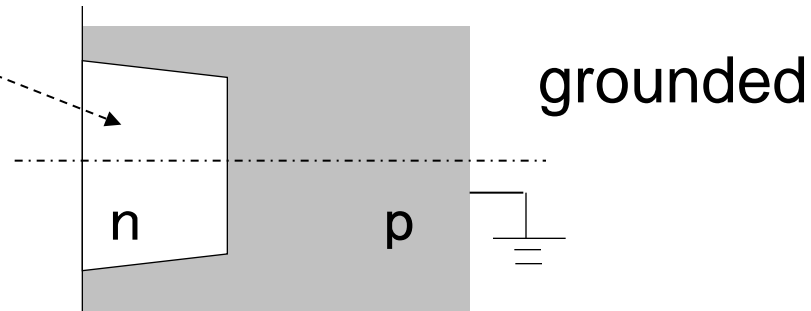
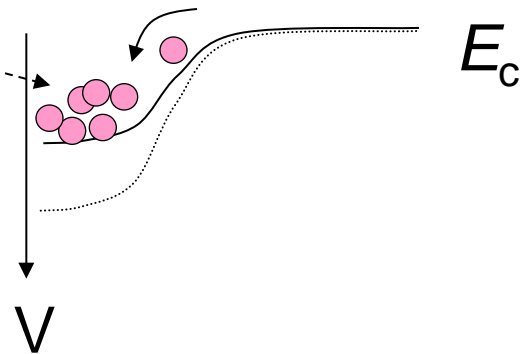
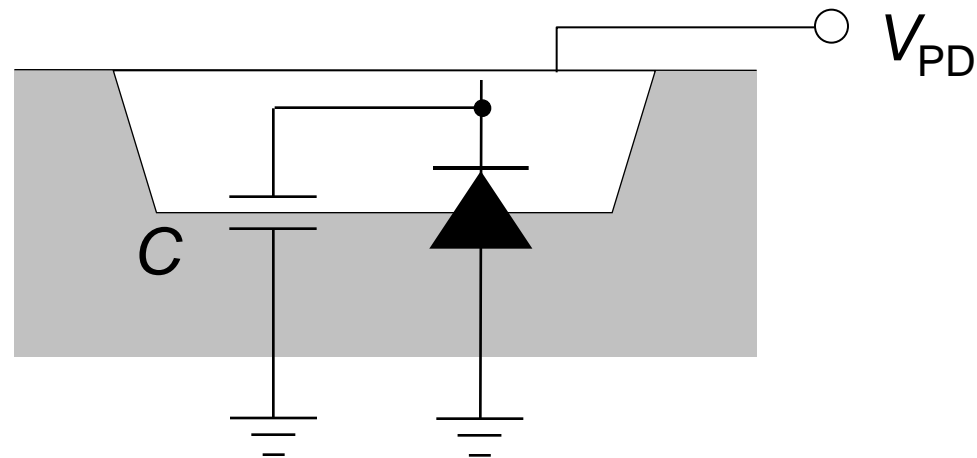


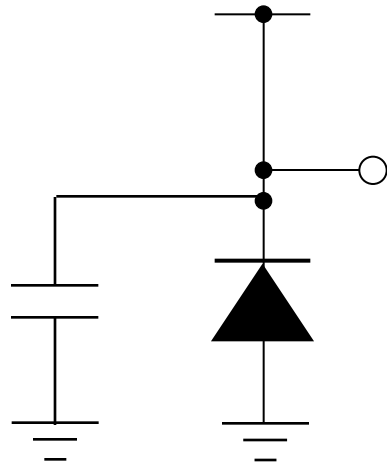
photo-generated charges



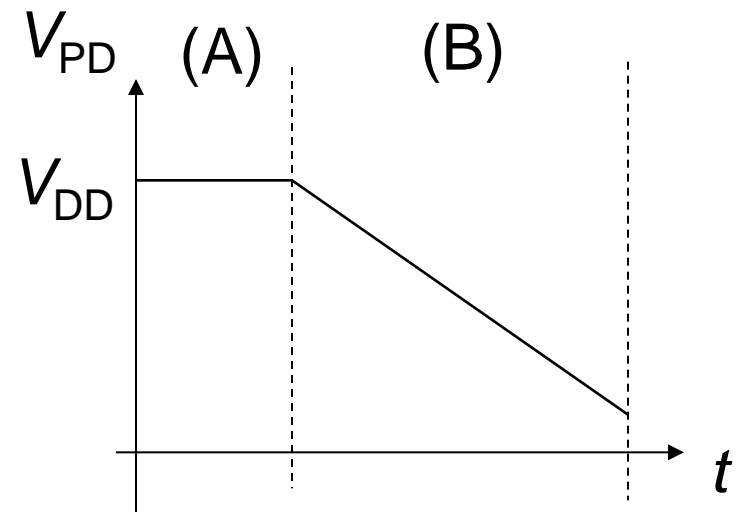
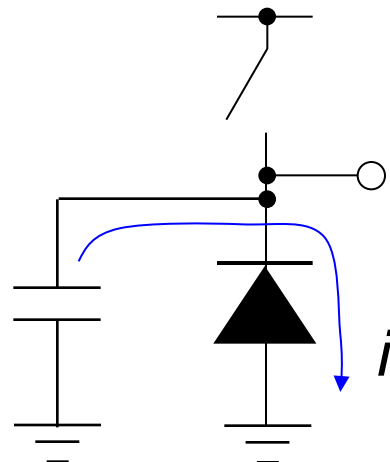
Schematic Description of Integration



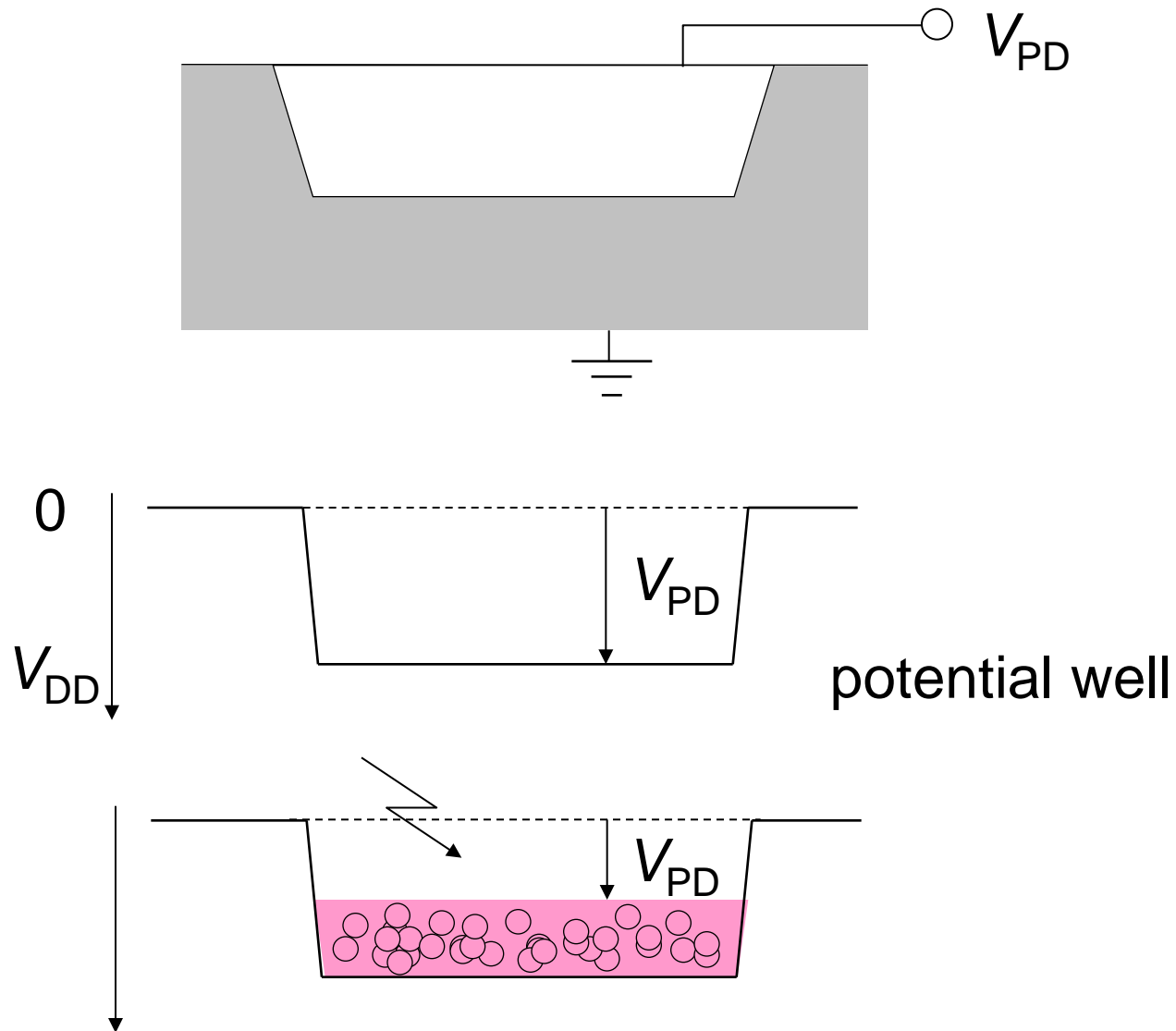
(A) Reset



(B) Integration



Potential Description of Integration



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- Lens and Optical Parts
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 - CCD / CMOS sensors
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CCD and CMOS image sensors

CCD: Charge-Coupled Devices

CMOS: Complementary Metal-Oxide-Semiconductor

- These terms do not refer to photo detecting structures!
- Fundamental difference is “how to readout the signal charge amount”

CCD sensor: $h\nu \longrightarrow Q \longrightarrow V$
within pixel

CMOS sensor: $h\nu \longrightarrow Q \longrightarrow V$
within pixel

CCD and CMOS image sensors

CCD sensors

Special fabrication process

Large power dissipation
(multiple high voltage required)

Difficult to be integrated
with computational
functionality

High image quality - high cost

CMOS sensors

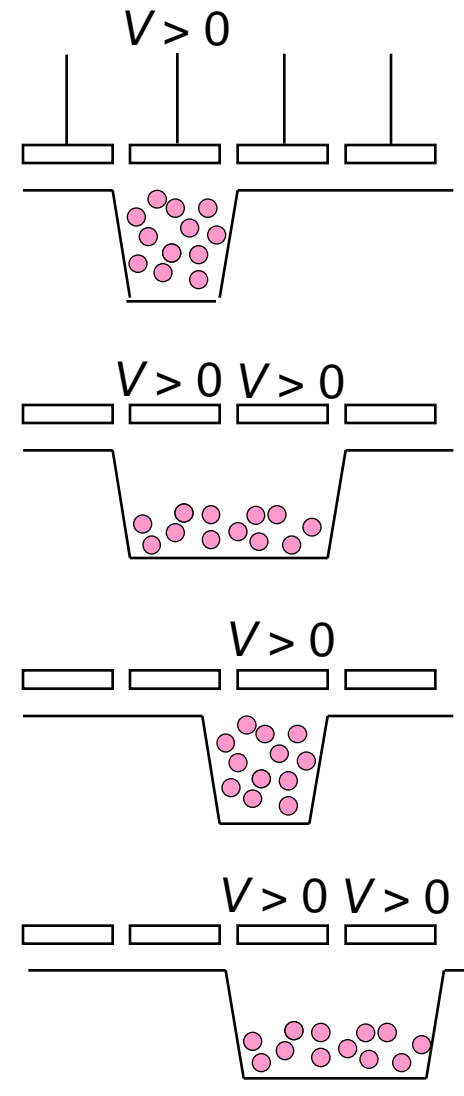
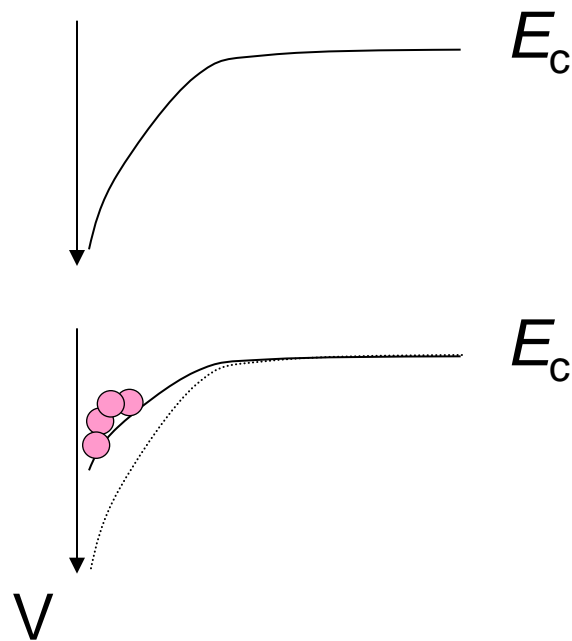
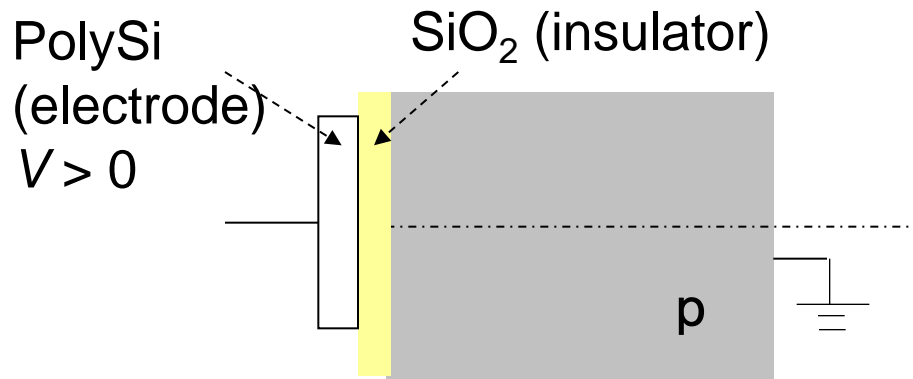
Standard CMOS process can be
used (but special process is also
used for high quality)

Low power consumption
(single CMOS level voltage)

Easy to be integrated with CMOS
processing circuits

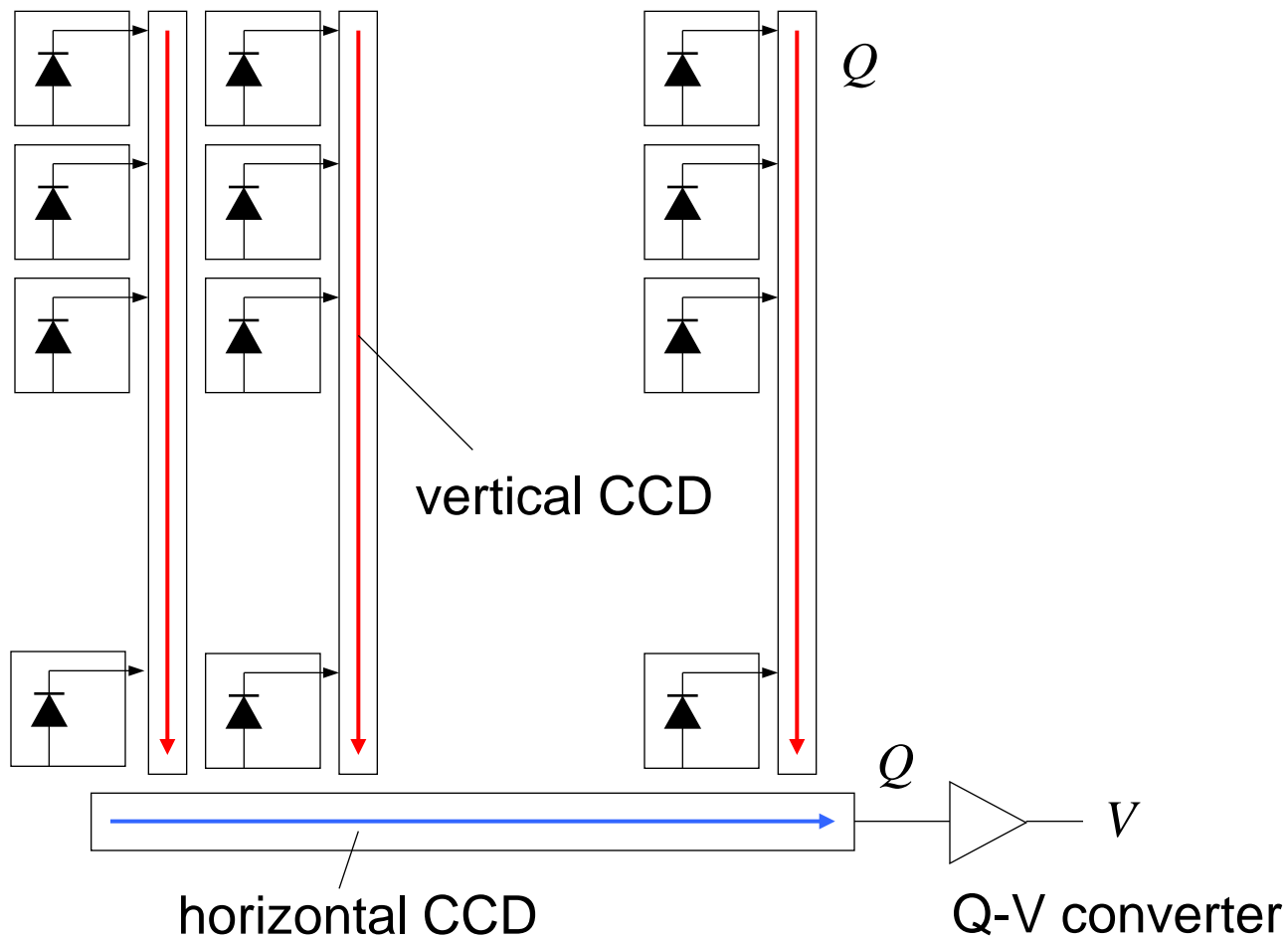
Varies from low quality – low cost
to high quality – high cost

CCD (Charge-Coupled Device)

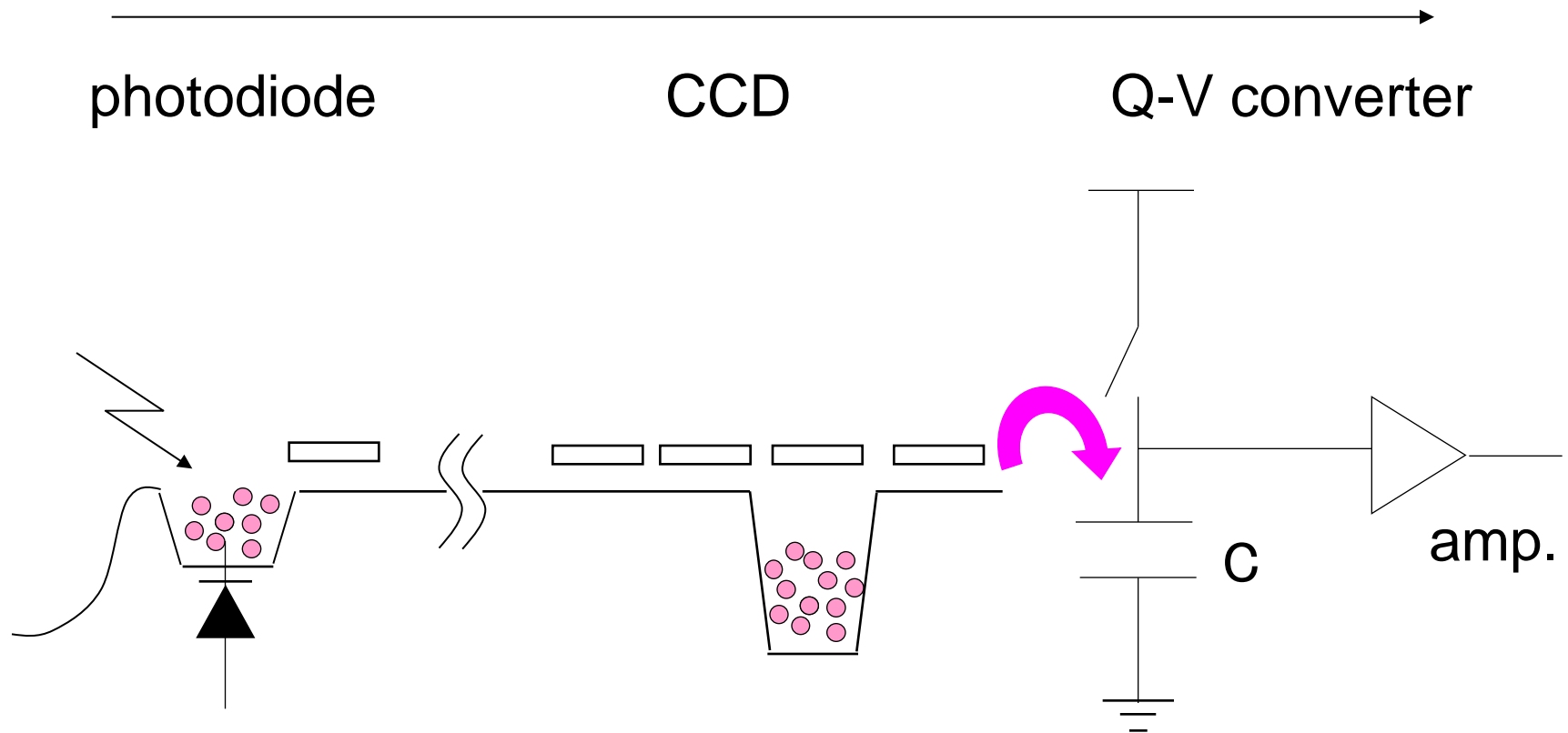


CCD Image Sensor

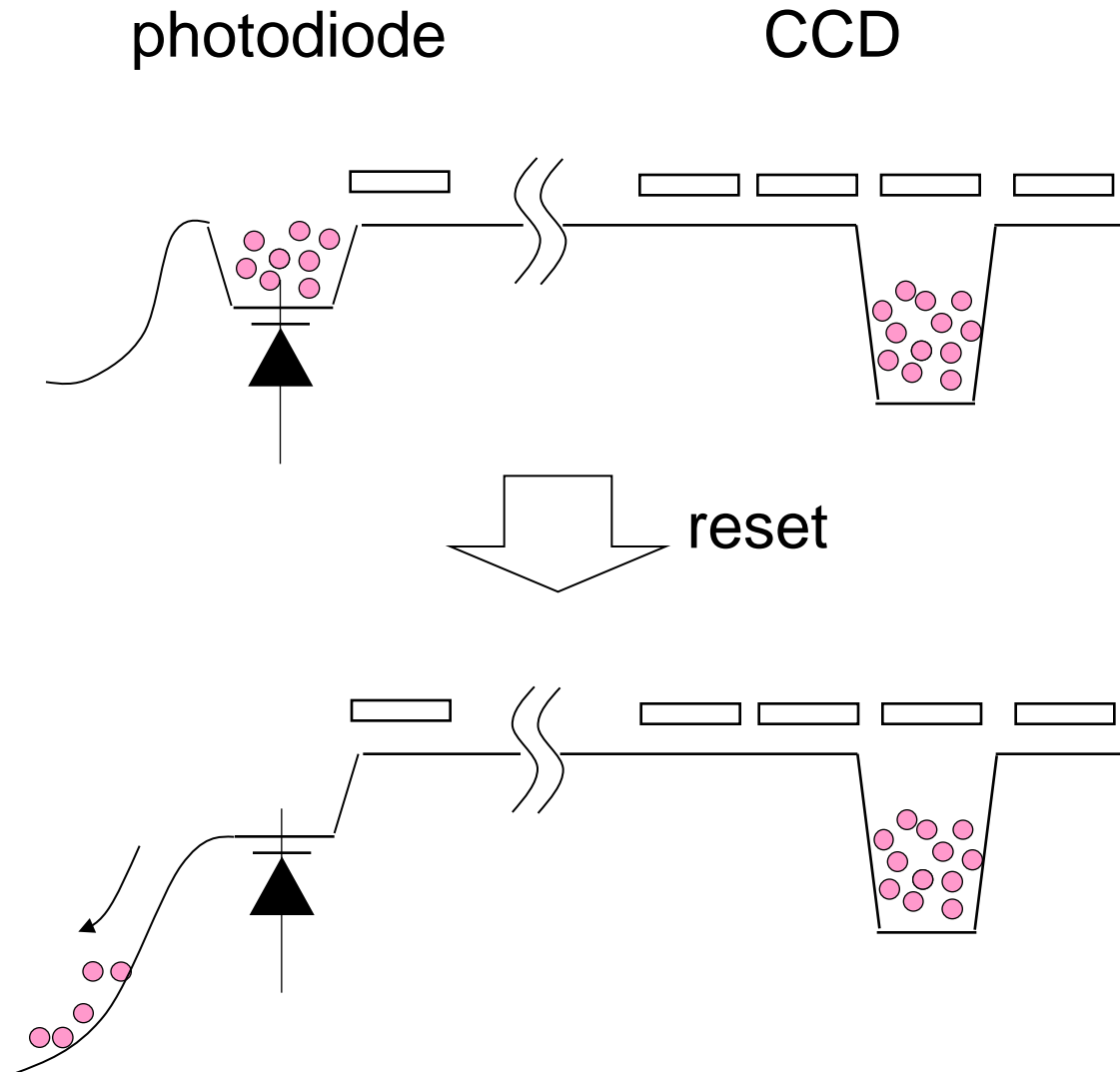
Interline Transfer CCD (IT-CCD)



Signals in a CCD sensor

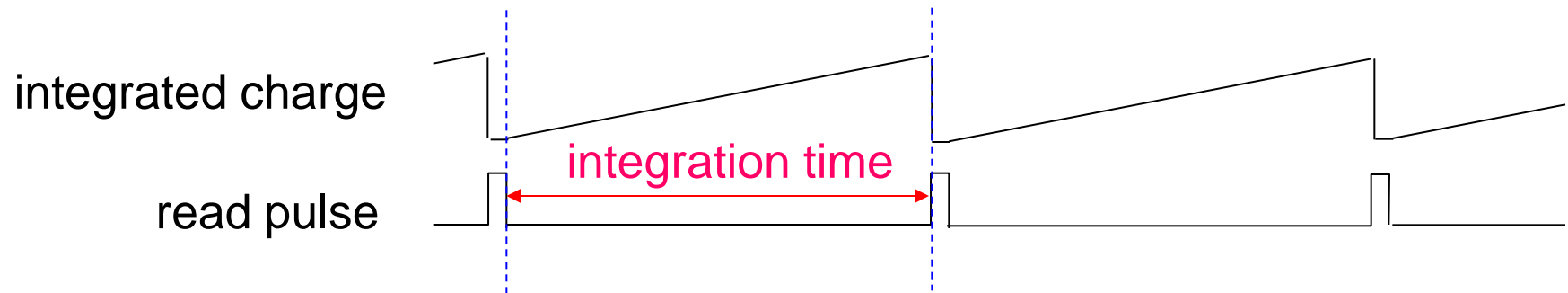


Resetting in IT-CCD

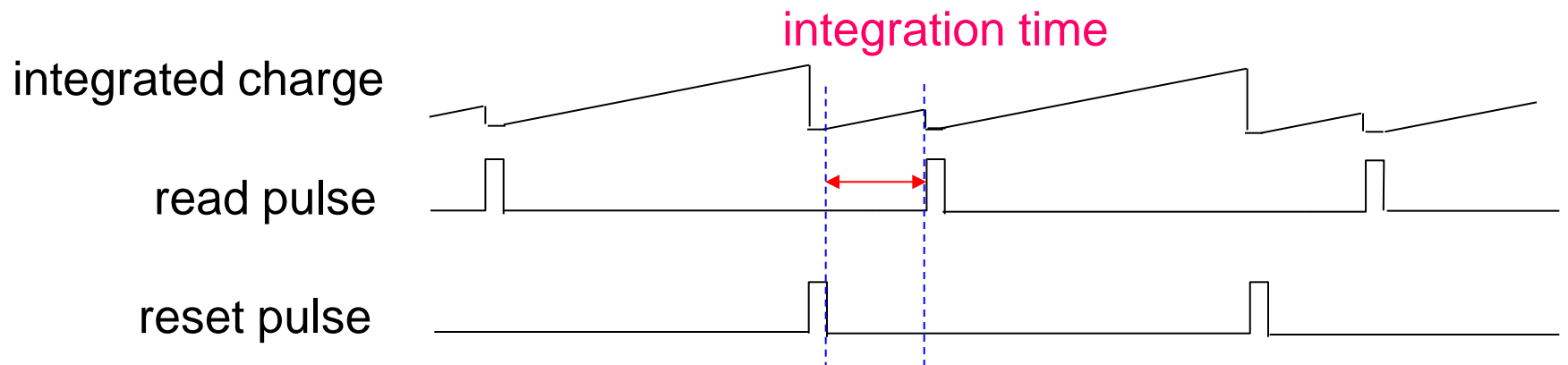


Electronic Shutters in CCD

IT-CCD (w/o electronic shutter):

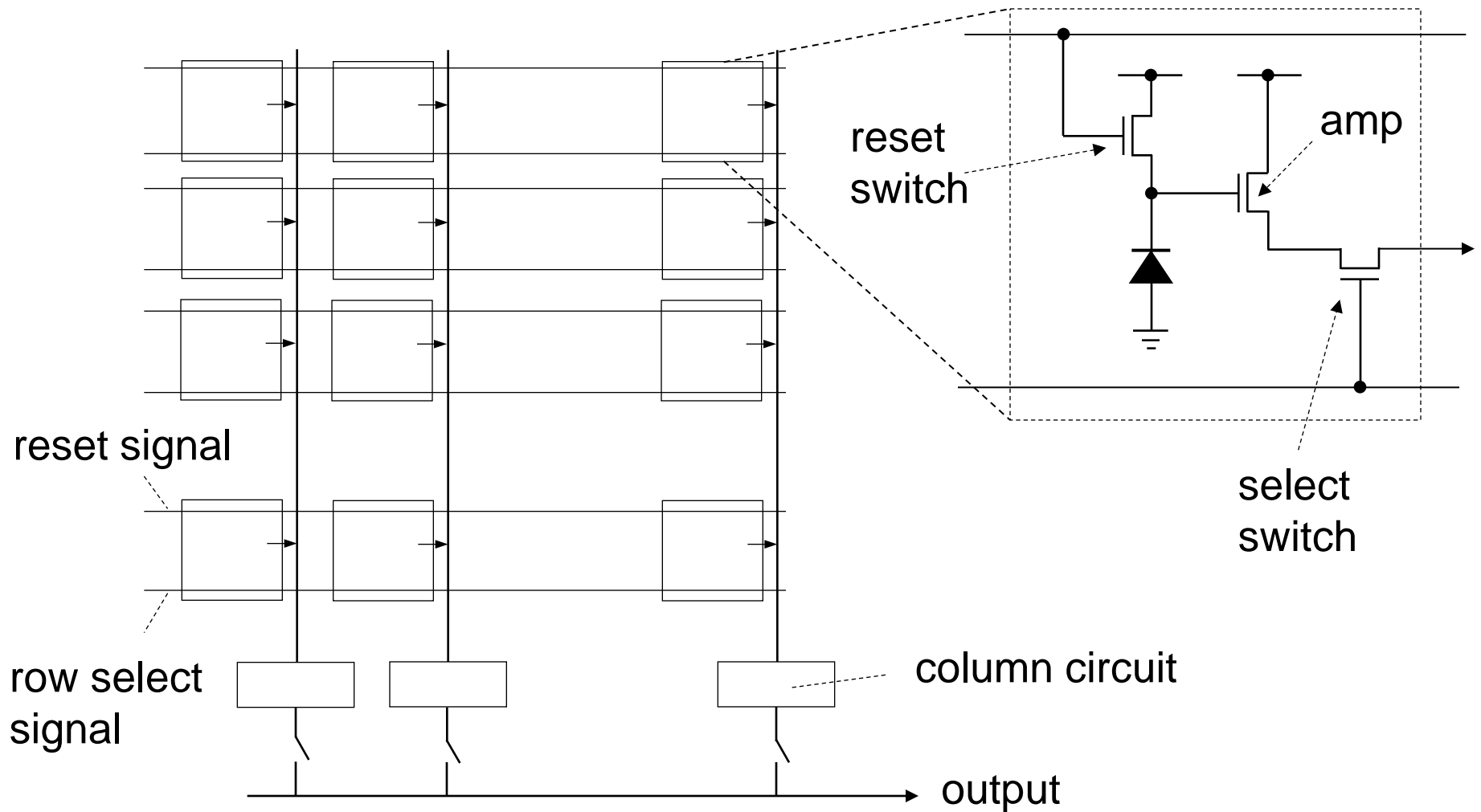


IT-CCD (with electronic shutter):

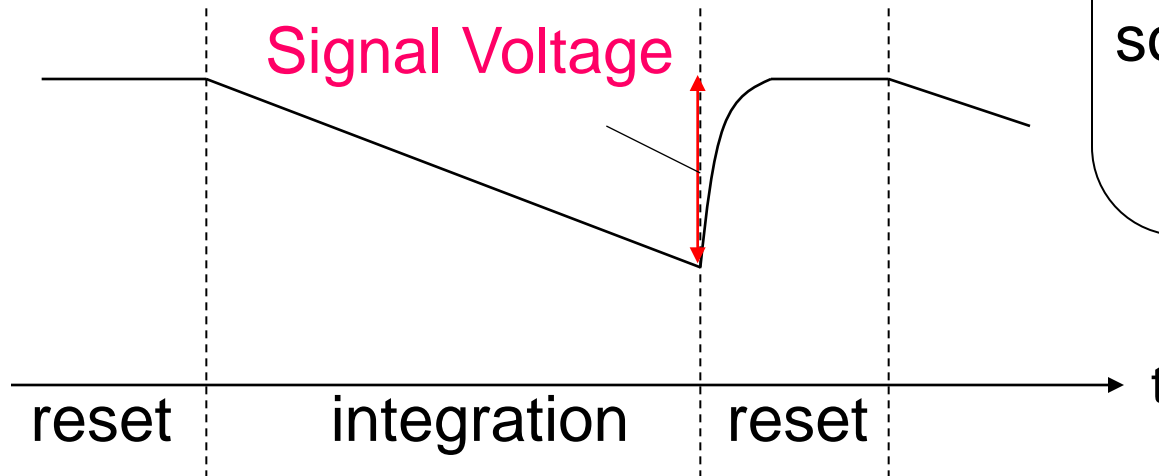
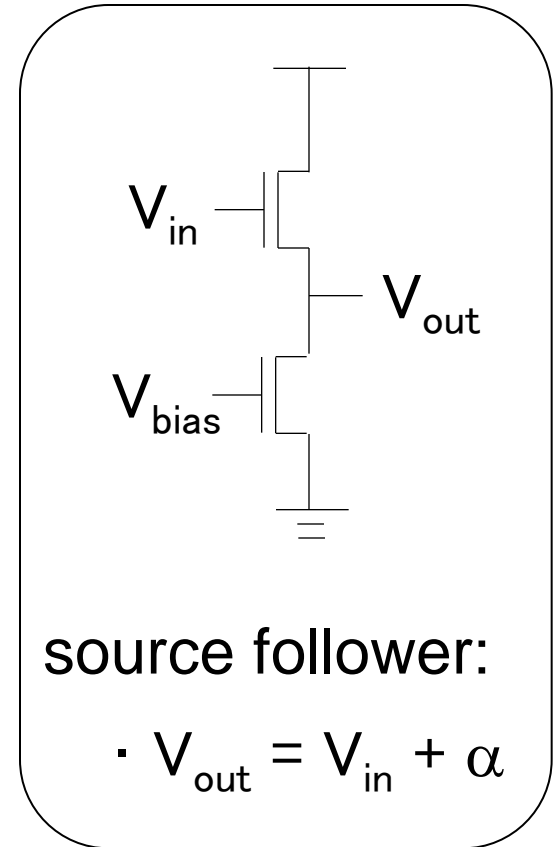
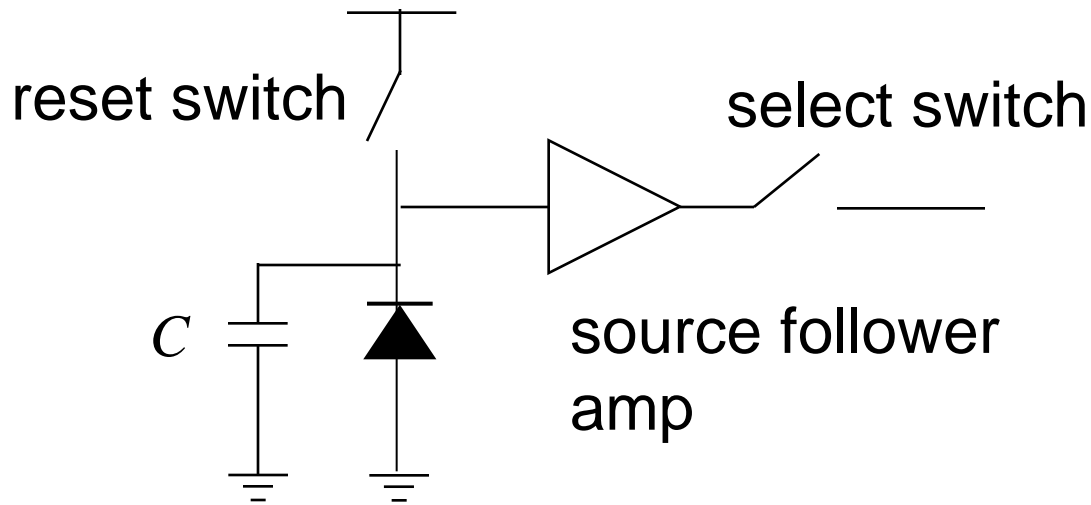


CMOS Image Sensor

3-transistor Active Pixel Sensor (3T-APS)

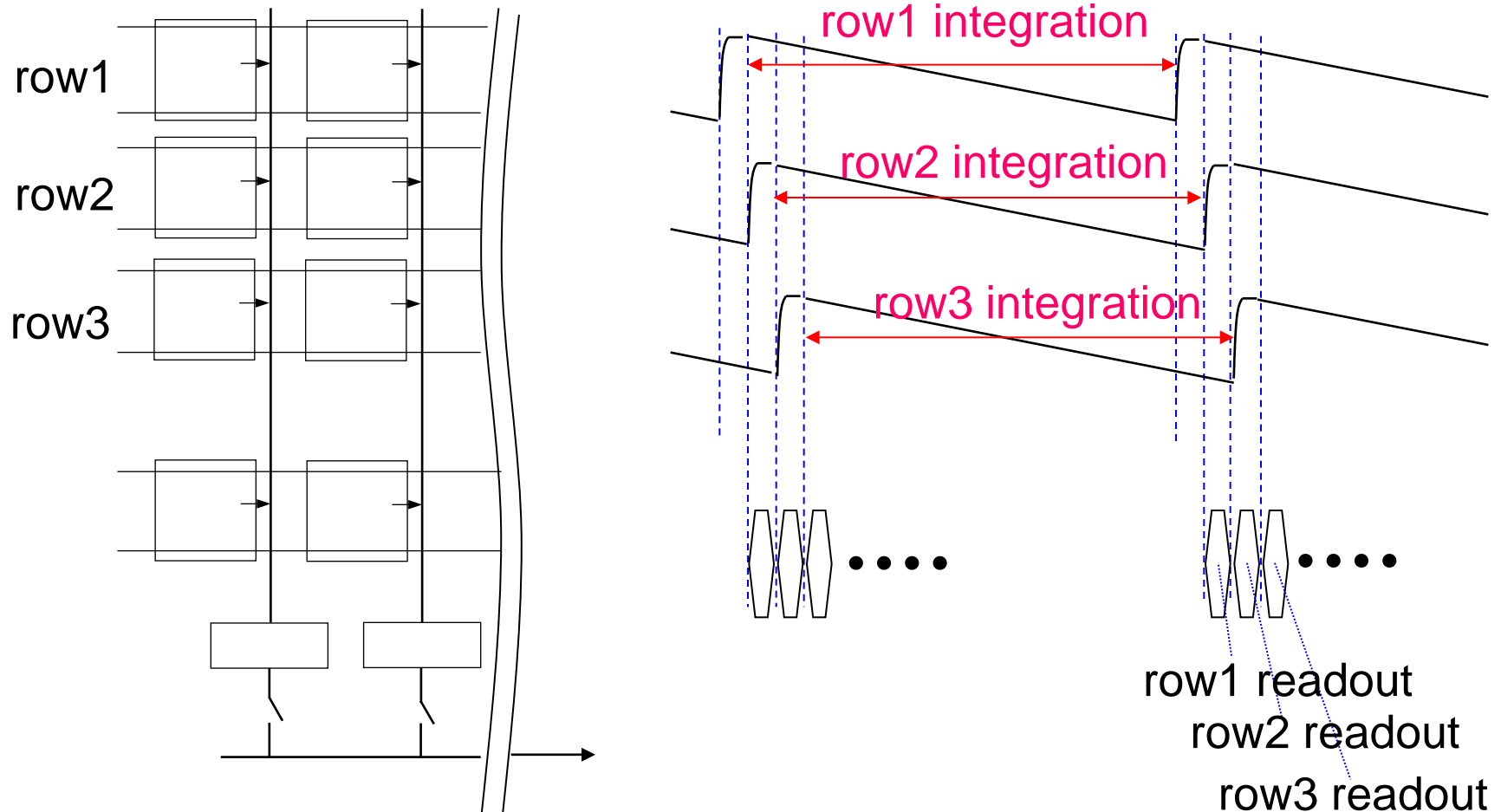


Signals in a CMOS sensor



Shutter Modes

While IT-CCDs operate in the **global shutter mode**,
3T-APS CMOS sensors operate in the **rolling shutter mode**



Rolling Shutter Example



A spinning propeller
taken by an iPhone camera

<http://scalarmotion.wordpress.com/2009/03/15/propeller-image-aliasing/>

Techniques for High-Speed Imaging

Parallel readout / Parallel ADC

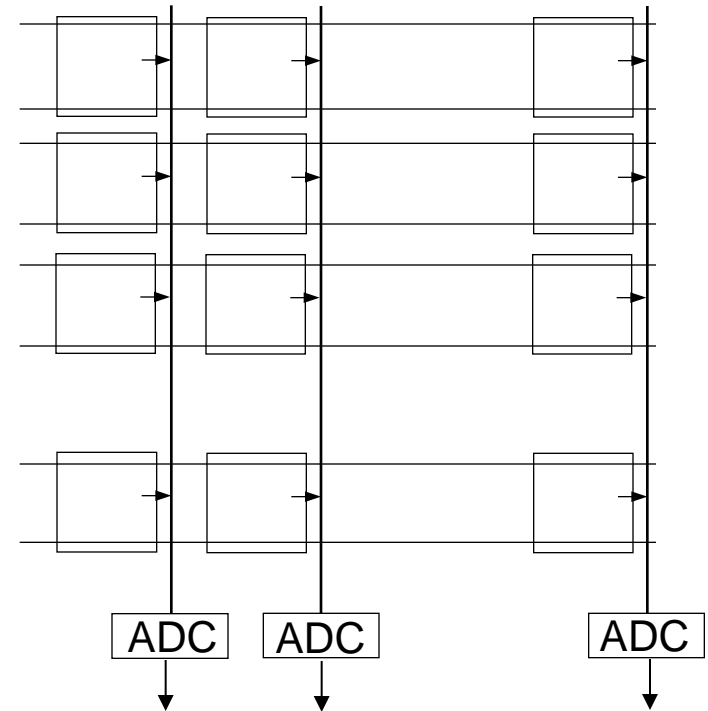
- column-parallel
- column-parallel x 2 (upper and lower)

Readout Modes

- sub frame, sub sampling
- binning (neighbor pixels are concatenated)
- (semi-)random access

Low-noise / High-sensitivity pixels

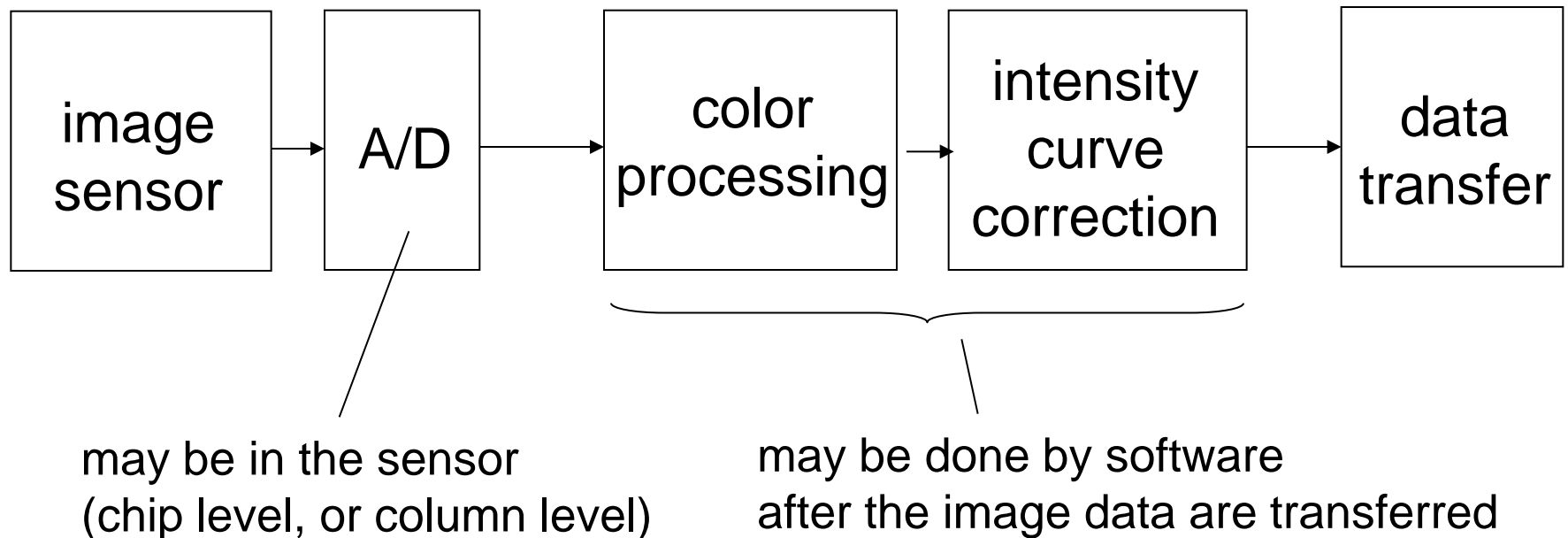
- micro lens
- back-illuminated sensor



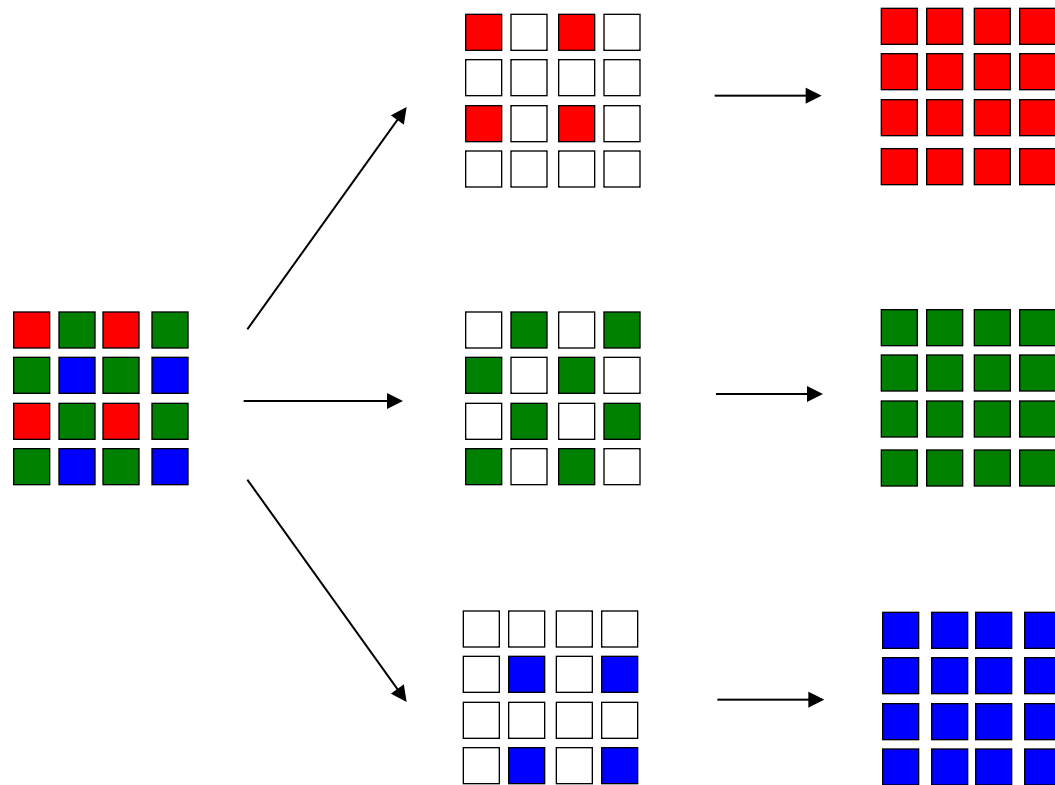
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In-Camera Processing

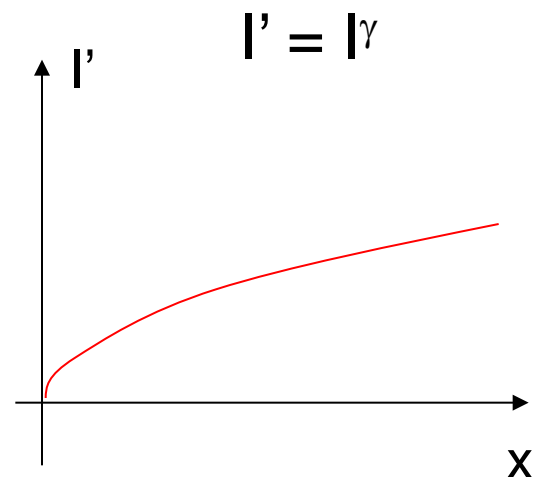
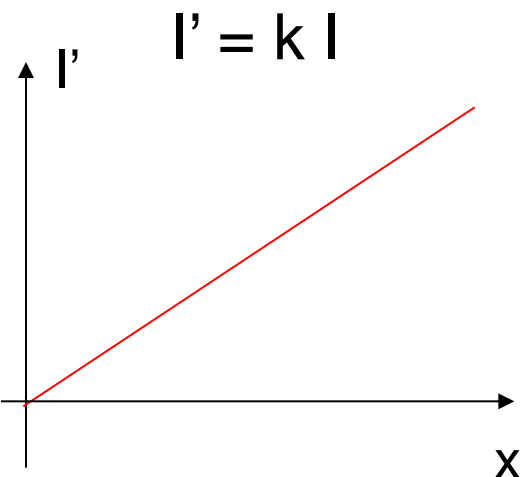
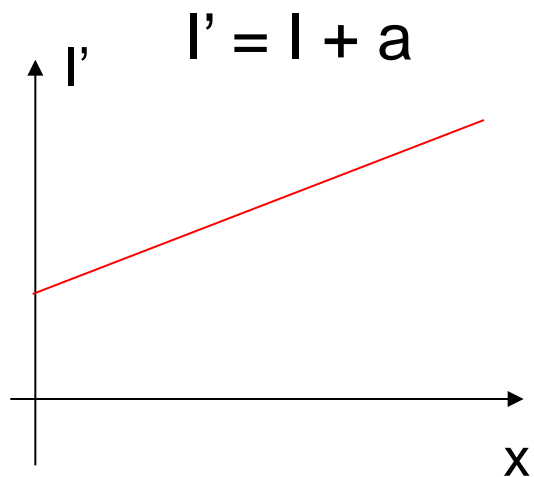
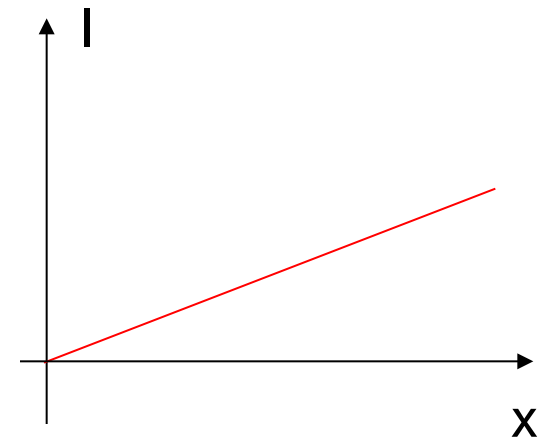
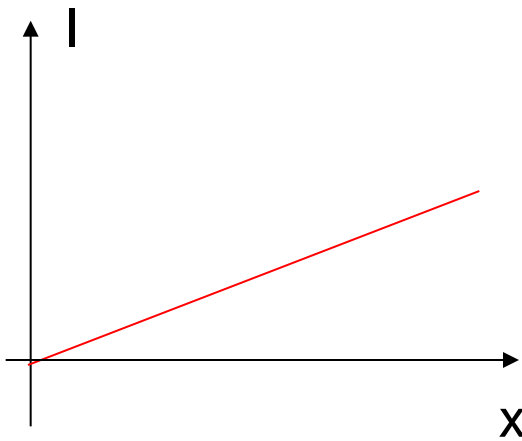
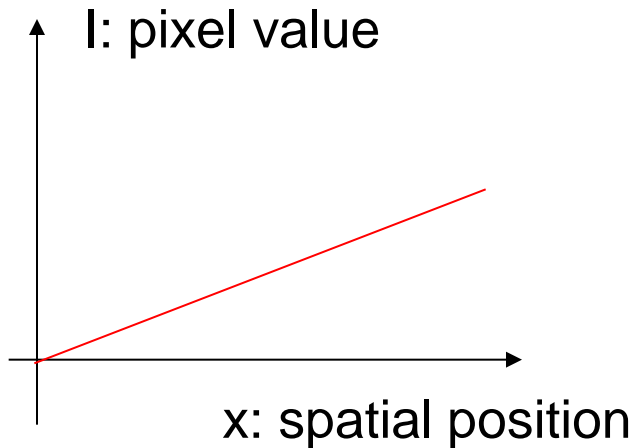


Color Processing (demosaicing)



- Can be done by software; but it takes computation time
- Can be done in camera; but it consumes 3 times transfer bandwidth

Brightness, Contrast, and Gamma



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Data Transfer

$8 \text{ [bits/pixel]} \times 1 \text{ M [pixels/frame]} \times 30 \text{ [fps]} = 240 \text{ M [bps]}$

$8 \text{ [bits/pixel]} \times 1 \text{ M [pixels/frame]} \times 1000 \text{ [fps]} = 8000 \text{ M [bps]}$

interface

max. bit rate

IEEE 1394a

400 Mbps

IEEE 1394b

800 Mbps

USB 2.0

480 Mbps

USB 3.0

5000 Mbps

Gigabit Ethernet

1000 Mbps

PCI Express 3.0

8000 Mbps / lane

Camera Link

2000 Mbps (base config.)

5440 Mbps (full config.)

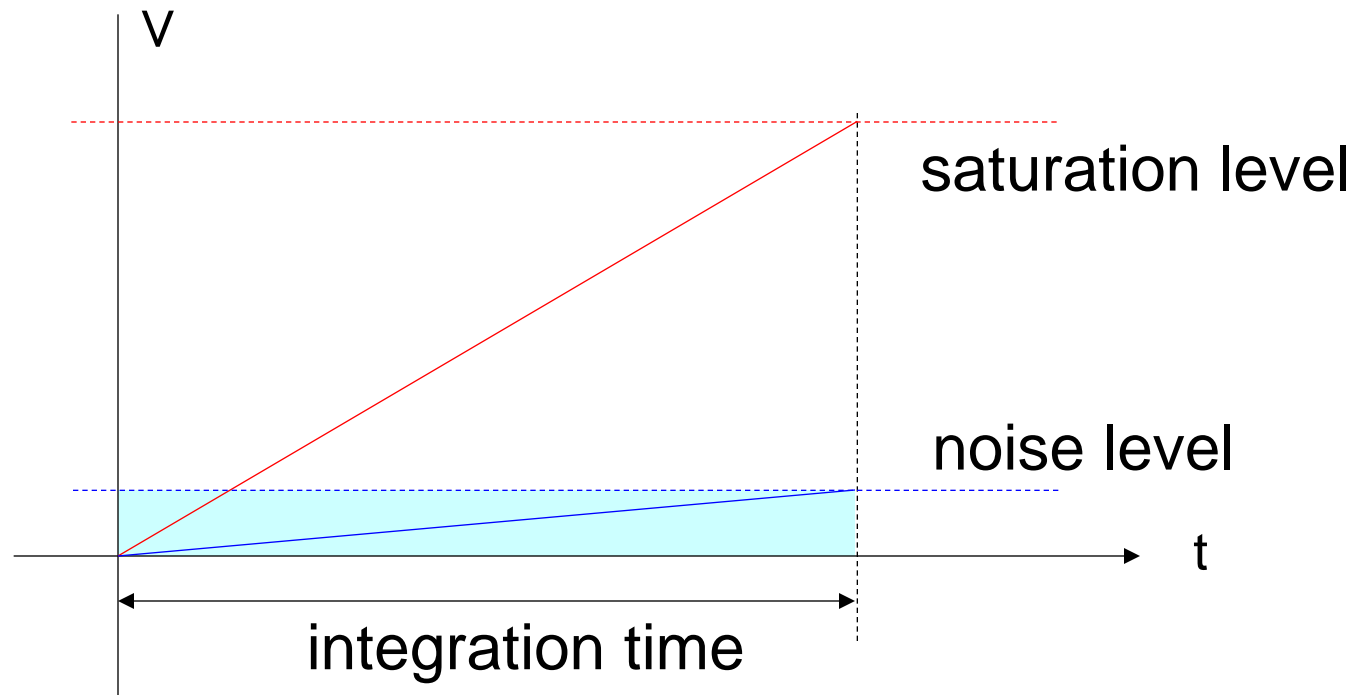
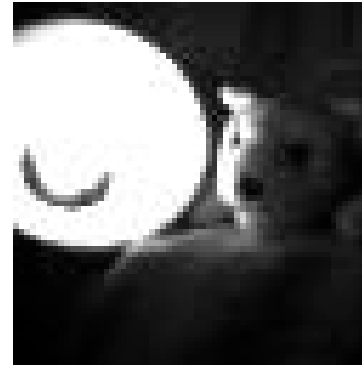
and more (extended config.)

Outline

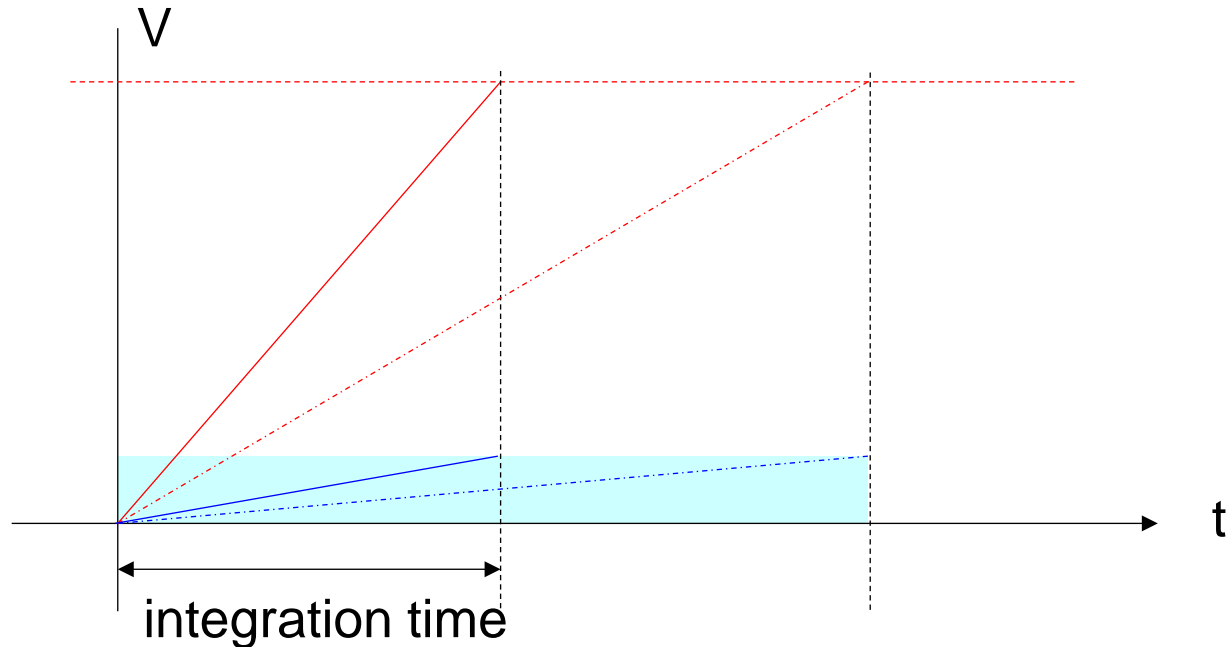
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Dynamic Range

$$\text{DR [dB]} = 20 \log \frac{i_{\text{upper}}}{i_{\text{lower}}}$$



Dynamic range and Integration time

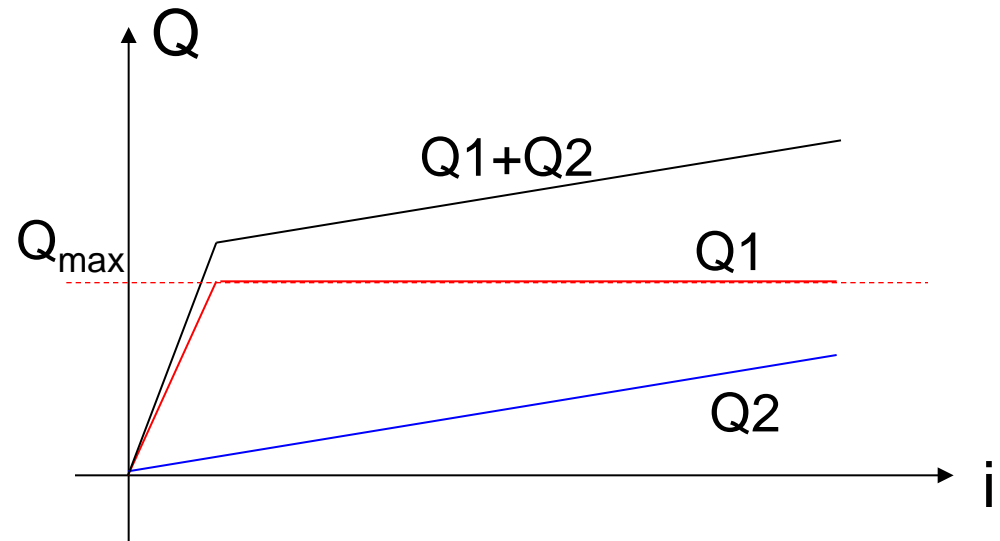
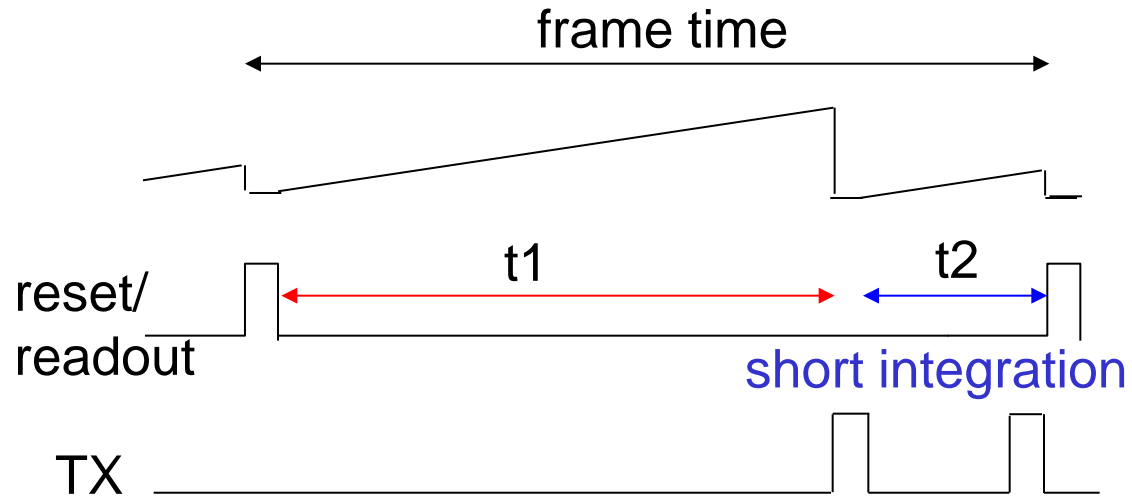
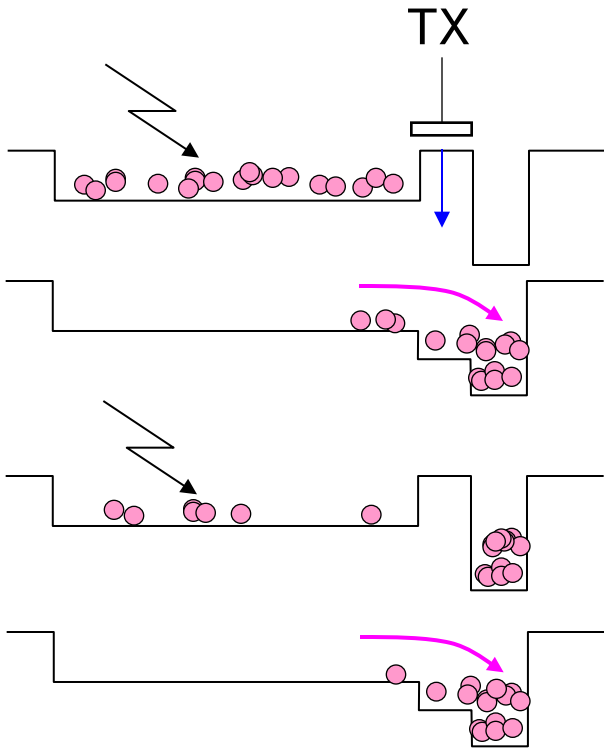


Simply modifying the integration time will not contribute to dynamic range enhancement.

Commonly used techniques utilize multiple integration times.

Dynamic Range Enhancement Example

MT9V403, Micron Technologies



$$Q_1 = \max(Q_{\max}, it_1)$$

$$Q_2 = \max(Q_{\max}, it_2)$$

$$Q = Q_1 + Q_2$$

References

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